

DS001-2 (v2.1) March 5, 2001

# Spartan-II 2.5V FPGA Family: Functional Description

**Preliminary Product Specification** 

## **Architectural Description**

## **Spartan-II Array**

The Spartan-II user-programmable gate array, shown in Figure 1, is composed of five major configurable elements:

- IOBs provide the interface between the package pins and the internal logic
- CLBs provide the functional elements for constructing most logic
- Dedicated block RAM memories of 4096 bits each
- Clock DLLs for clock-distribution delay compensation and clock domain control
- Versatile multi-level interconnect structure

As can be seen in Figure 1, the CLBs form the central logic structure with easy access to all support and routing structures. The IOBs are located around all the logic and memory elements for easy and quick routing of signals on and off the chip.

Values stored in static memory cells control all the configurable logic elements and interconnect resources. These values load into the memory cells on power-up, and can reload if necessary to change the function of the device.

Each of these elements will be discussed in detail in the following sections.

## **Input/Output Block**

The Spartan-II IOB, as seen in Figure 1, features inputs and outputs that support a wide variety of I/O signaling standards. These high-speed inputs and outputs are capable of supporting various state of the art memory and bus interfaces. Table 1 lists several of the standards which are supported along with the required reference, output and termination voltages needed to meet the standard.

The three IOB registers function either as edge-triggered D-type flip-flops or as level- sensitive latches. Each IOB has a clock signal (CLK) shared by the three registers and independent Clock Enable (CE) signals for each register.



Figure 1: Spartan-II Input/Output Block (IOB)

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www.xilinx.com 1-800-255-7778 In addition to the CLK and CE control signals, the three registers share a Set/Reset (SR). For each register, this signal can be independently configured as a synchronous Set, a synchronous Reset, an asynchronous Preset, or an asynchronous Clear.

A feature not shown in the block diagram, but controlled by the software, is polarity control. The input and output buffers and all of the IOB control signals have independent polarity controls.

Optional pull-up and pull-down resistors and an optional weak-keeper circuit are attached to each pad. Prior to configuration all outputs not involved in configuration are forced into their high-impedance state. The pull-down resistors and the weak-keeper circuits are inactive, but inputs may optionally be pulled up.

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I/O Standard	Input Reference Voltage (V <sub>REF</sub> )	Output Source Voltage (V <sub>CCO</sub> )	Board Termination Voltage (V <sub>TT</sub> )
LVTTL (2-24 mA)	N/A	3.3	N/A
LVCMOS2	N/A	2.5	N/A
PCI (3V/5V, 33 MHz/66 MHz)	N/A	3.3	N/A
GTL	0.8	N/A	1.2
GTL+	1.0	N/A	1.5
HSTL Class I	0.75	1.5	0.75
HSTL Class III	0.9	1.5	1.5
HSTL Class IV	0.9	1.5	1.5
SSTL3 Class I and II	1.5	3.3	1.5
SSTL2 Class I and II	1.25	2.5	1.25
СТТ	1.5	3.3	1.5
AGP-2X	1.32	3.3	N/A

#### Table 1: Standards Supported by I/O (Typical Values)

The activation of pull-up resistors prior to configuration is controlled on a global basis by the configuration mode pins. If the pull-up resistors are not activated, all the pins will float. Consequently, external pull-up or pull-down resistors must be provided on pins required to be at a well-defined logic level prior to configuration.

All pads are protected against damage from electrostatic discharge (ESD) and from over-voltage transients. Two forms of over-voltage protection are provided, one that permits 5V compliance, and one that does not. For 5V compliance, a zener-like structure connected to ground turns on when the output rises to approximately 6.5V. When 5V com-

pliance is not required, a conventional clamp diode may be connected to the output supply voltage,  $V_{CCO}$ . The type of over-voltage protection can be selected independently for each pad.

All Spartan-II IOBs support IEEE 1149.1-compatible boundary scan testing.

#### Input Path

A buffer In the Spartan-II IOB input path routes the input signal either directly to internal logic or through an optional input flip-flop.

An optional delay element at the D-input of this flip-flop eliminates pad-to-pad hold time. The delay is matched to the internal clock-distribution delay of the FPGA, and when used, assures that the pad-to-pad hold time is zero.

Each input buffer can be configured to conform to any of the low-voltage signaling standards supported. In some of these standards the input buffer utilizes a user-supplied threshold voltage,  $V_{REF}$  The need to supply  $V_{REF}$  imposes constraints on which standards can used in close proximity to each other. See I/O Banking, page 3.

There are optional pull-up and pull-down resistors at each input for use after configuration.

#### **Output Path**

The output path includes a 3-state output buffer that drives the output signal onto the pad. The output signal can be routed to the buffer directly from the internal logic or through an optional IOB output flip-flop.

The 3-state control of the output can also be routed directly from the internal logic or through a flip-flip that provides synchronous enable and disable.

Each output driver can be individually programmed for a wide range of low-voltage signaling standards. Each output buffer can source up to 24 mA and sink up to 48 mA. Drive strength and slew rate controls minimize bus transients.

In most signaling standards, the output high voltage depends on an externally supplied  $V_{CCO}$  voltage. The need to supply  $V_{CCO}$  imposes constraints on which standards can be used in close proximity to each other. See I/O Banking.

An optional weak-keeper circuit is connected to each output. When selected, the circuit monitors the voltage on the pad and weakly drives the pin High or Low to match the input signal. If the pin is connected to a multiple-source signal, the weak keeper holds the signal in its last state if all drivers are disabled. Maintaining a valid logic level in this way helps eliminate bus chatter.

Because the weak-keeper circuit uses the IOB input buffer to monitor the input level, an appropriate  $V_{REF}$  voltage must be provided if the signaling standard requires one. The provision of this voltage must comply with the I/O banking rules.

## I/O Banking

Some of the I/O standards described above require  $V_{CCO}$  and/or  $V_{REF}$  voltages. These voltages are externally connected to device pins that serve groups of IOBs, called banks. Consequently, restrictions exist about which I/O standards can be combined within a given bank.

Eight I/O banks result from separating each edge of the FPGA into two banks (see Figure 2). Each bank has multiple  $V_{CCO}$  pins which must be connected to the same voltage. Voltage is determined by the output standards in use.



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Figure 2: Spartan-II I/O Banks

Within a bank, output standards may be mixed only if they use the same V<sub>CCO</sub>. Compatible standards are shown in Table 2. GTL and GTL+ appear under all voltages because their open-drain outputs do not depend on V<sub>CCO</sub>.

#### Table 2: Compatible Output Standards

V <sub>cco</sub>	Compatible Standards
3.3V	PCI, LVTTL, SSTL3 I, SSTL3 II, CTT, AGP, GTL, GTL+
2.5V	SSTL2 I, SSTL2 II, LVCMOS2, GTL, GTL+
1.5V	HSTL I, HSTL III, HSTL IV, GTL, GTL+

Some input standards require a user-supplied threshold voltage,  $V_{REF}$  In this case, certain user-I/O pins are automatically configured as inputs for the  $V_{REF}$  voltage. About one in six of the I/O pins in the bank assume this role.

 $V_{\sf REF}$  pins within a bank are interconnected internally and consequently only one  $V_{\sf REF}$  voltage can be used within

each bank. All  $V_{REF}$  pins in the bank, however, must be connected to the external voltage source for correct operation.

In a bank, inputs requiring V<sub>REF</sub> can be mixed with those that do not but only one V<sub>REF</sub> voltage may be used within a bank. Input buffers that use V<sub>REF</sub> are not 5V tolerant. LVTTL, LVCMOS2, and PCI are 5V tolerant. The V<sub>CCO</sub> and V<sub>REF</sub> pins for each bank appear in the device pinout tables.

Within a given package, the number of V<sub>REF</sub> and V<sub>CCO</sub> pins can vary depending on the size of device. In larger devices, more I/O pins convert to V<sub>REF</sub> pins. Since these are always a superset of the V<sub>REF</sub> pins used for smaller devices, it is possible to design a PCB that permits migration to a larger device. All V<sub>REF</sub> pins for the largest device anticipated must be connected to the V<sub>REF</sub> voltage, and not used for I/O.

#### Table 3: Independent Banks Available

Package	VQ100	CS144	FG256
	PQ208	TQ144	FG456
Independent Banks	1	4	8

## **Configurable Logic Block**

The basic building block of the Spartan-II CLB is the logic cell (LC). An LC includes a 4-input function generator, carry logic, and storage element. Output from the function generator in each LC drives the CLB output and the D input of the flip-flop. Each Spartan-II CLB contains four LCs, organized in two similar slices; a single slice is shown in Figure 3.

In addition to the four basic LCs, the Spartan-II CLB contains logic that combines function generators to provide functions of five or six inputs.

#### Look-Up Tables

Spartan-II function generators are implemented as 4-input look-up tables (LUTs). In addition to operating as a function generator, each LUT can provide a  $16 \times 1$ -bit synchronous RAM. Furthermore, the two LUTs within a slice can be combined to create a  $16 \times 2$ -bit or  $32 \times 1$ -bit synchronous RAM, or a  $16 \times 1$ -bit dual-port synchronous RAM.

The Spartan-II LUT can also provide a 16-bit shift register that is ideal for capturing high-speed or burst-mode data. This mode can also be used to store data in applications such as Digital Signal Processing.

#### Storage Elements

Storage elements in the Spartan-II slice can be configured either as edge-triggered D-type flip-flops or as level-sensitive latches. The D inputs can be driven either by function generators within the slice or directly from slice inputs, bypassing the function generators.



Figure 3: Spartan-II CLB Slice (two identical slices in each CLB)

In addition to Clock and Clock Enable signals, each slice has synchronous set and reset signals (SR and BY). SR forces a storage element into the initialization state specified for it in the configuration. BY forces it into the opposite state. Alternatively, these signals may be configured to operate asynchronously.

All control signals are independently invertible, and are shared by the two flip-flops within the slice.

#### Additional Logic

The F5 multiplexer in each slice combines the function generator outputs. This combination provides either a function generator that can implement any 5-input function, a 4:1 multiplexer, or selected functions of up to nine inputs.

Similarly, the F6 multiplexer combines the outputs of all four function generators in the CLB by selecting one of the F5-multiplexer outputs. This permits the implementation of any 6-input function, an 8:1 multiplexer, or selected functions of up to 19 inputs.

Each CLB has four direct feedthrough paths, one per LC. These paths provide extra data input lines or additional local routing that does not consume logic resources.

#### Arithmetic Logic

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Dedicated carry logic provides fast arithmetic carry capability for high-speed arithmetic functions. The Spartan-II CLB supports two separate carry chains, one per slice. The height of the carry chains is two bits per CLB.

The arithmetic logic includes an XOR gate that allows a 1-bit full adder to be implemented within an LC. In addition, a dedicated AND gate improves the efficiency of multiplier implementation.

The dedicated carry path can also be used to cascade function generators for implementing wide logic functions.

#### **BUFTs**

Each Spartan-II CLB contains two 3-state drivers (BUFTs) that can drive on-chip busses. See **Dedicated Routing**, page 6. Each Spartan-II BUFT has an independent 3-state control pin and an independent input pin.

#### **Block RAM**

Spartan-II FPGAs incorporate several large block RAM memories. These complement the distributed RAM Look-Up Tables (LUTs) that provide shallow memory structures implemented in CLBs.

Block RAM memory blocks are organized in columns. All Spartan-II devices contain two such columns, one along each vertical edge. These columns extend the full height of the chip. Each memory block is four CLBs high, and consequently, a Spartan-II device eight CLBs high will contain two memory blocks per column, and a total of four blocks.

Table 4:	Spartan-II	<b>Block</b>	RAM	Amounts
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Spartan-II Device	# of Blocks	Total Block RAM Bits
XC2S15	4	16K
XC2S30	6	24K
XC2S50	8	32K
XC2S100	10	40K
XC2S150	12	48K
XC2S200	14	56K

Each block RAM cell, as illustrated in Figure 4, is a fully synchronous dual-ported 4096-bit RAM with independent control signals for each port. The data widths of the two ports can be configured independently, providing built-in bus-width conversion.



Figure 4: Dual-Port Block RAM

Table 5 shows the depth and width aspect ratios for the block RAM.

Table 5: Block RAM Port Aspect Ratios

Width	Depth	ADDR Bus	Data Bus
1	4096	ADDR<11:0>	DATA<0>
2	2048	ADDR<10:0>	DATA<1:0>
4	1024	ADDR<9:0>	DATA<3:0>
8	512	ADDR<8:0>	DATA<7:0>
16	256	ADDR<7:0>	DATA<15:0>

The Spartan-II block RAM also includes dedicated routing to provide an efficient interface with both CLBs and other block RAMs.

## **Programmable Routing Matrix**

It is the longest delay path that limits the speed of any worst-case design. Consequently, the Spartan-II routing architecture and its place-and-route software were defined in a single optimization process. This joint optimization minimizes long-path delays, and consequently, yields the best system performance.

The joint optimization also reduces design compilation times because the architecture is software-friendly. Design cycles are correspondingly reduced due to shorter design iteration times.

#### Local Routing

The local routing resources, as shown in Figure 5, provide the following three types of connections:

- Interconnections among the LUTs, flip-flops, and General Routing Matrix (GRM)
- Internal CLB feedback paths that provide high-speed connections to LUTs within the same CLB, chaining

them together with minimal routing delay

Direct paths that provide high-speed connections between horizontally adjacent CLBs, eliminating the delay of the GRM



Figure 5: Spartan-II Local Routing

#### General Purpose Routing

Most Spartan-II signals are routed on the general purpose routing, and consequently, the majority of interconnect resources are associated with this level of the routing hierarchy. The general routing resources are located in horizontal and vertical routing channels associated with the rows and columns CLBs. The general-purpose routing resources are listed below.

- Adjacent to each CLB is a General Routing Matrix (GRM). The GRM is the switch matrix through which horizontal and vertical routing resources connect, and is also the means by which the CLB gains access to the general purpose routing.
- 24 single-length lines route GRM signals to adjacent

GRMs in each of the four directions.

- 96 buffered Hex lines route GRM signals to other GRMs six blocks away in each one of the four directions. Organized in a staggered pattern, Hex lines may be driven only at their endpoints. Hex-line signals can be accessed either at the endpoints or at the midpoint (three blocks from the source). One third of the Hex lines are bidirectional, while the remaining ones are unidirectional.
- 12 Longlines are buffered, bidirectional wires that distribute signals across the device quickly and efficiently. Vertical Longlines span the full height of the device, and horizontal ones span the full width of the device.

#### I/O Routing

Spartan-II devices have additional routing resources around their periphery that form an interface between the CLB array and the IOBs. This additional routing, called the VersaRing, facilitates pin-swapping and pin-locking, such that logic redesigns can adapt to existing PCB layouts. Time-to-market is reduced, since PCBs and other system components can be manufactured while the logic design is still in progress.

#### **Dedicated Routing**

Some classes of signal require dedicated routing resources to maximize performance. In the Spartan-II architecture, dedicated routing resources are provided for two classes of signal.

- Horizontal routing resources are provided for on-chip 3-state busses. Four partitionable bus lines are provided per CLB row, permitting multiple busses within a row, as shown in Figure 6.
- Two dedicated nets per CLB propagate carry signals vertically to the adjacent CLB.



Figure 6: BUFT Connections to Dedicated Horizontal Bus Lines

## **Global Routing**

Global Routing resources distribute clocks and other signals with very high fanout throughout the device. Spartan-II devices include two tiers of global routing resources referred to as primary and secondary global routing resources.

- The primary global routing resources are four dedicated global nets with dedicated input pins that are designed to distribute high-fanout clock signals with minimal skew. Each global clock net can drive all CLB, IOB, and block RAM clock pins. The primary global nets may only be driven by global buffers. There are four global buffers, one for each global net.
- The secondary global routing resources consist of 24 backbone lines, 12 across the top of the chip and 12 across bottom. From these lines, up to 12 unique signals per column can be distributed via the 12 longlines in the column. These secondary resources are more flexible than the primary resources since they are not restricted to routing only to clock pins.

## **Clock Distribution**

The Spartan-II family provides high-speed, low-skew clock distribution through the primary global routing resources described above. A typical clock distribution net is shown in Figure 7.

Four global buffers are provided, two at the top center of the device and two at the bottom center. These drive the four primary global nets that in turn drive any clock pin.

Four dedicated clock pads are provided, one adjacent to each of the global buffers. The input to the global buffer is selected either from these pads or from signals in the general purpose routing.



Figure 7: Global Clock Distribution Network

## Delay-Locked Loop (DLL)

Associated with each global clock input buffer is a fully digital Delay-Locked Loop (DLL) that can eliminate skew between the clock input pad and internal clock-input pins throughout the device. Each DLL can drive two global clock networks. The DLL monitors the input clock and the distributed clock, and automatically adjusts a clock delay element. Additional delay is introduced such that clock edges reach internal flip-flops exactly one clock period after they arrive at the input. This closed-loop system effectively eliminates clock-distribution delay by ensuring that clock edges arrive at internal flip-flops in synchronism with clock edges arriving at the input.

In addition to eliminating clock-distribution delay, the DLL provides advanced control of multiple clock domains. The DLL provides four quadrature phases of the source clock, can double the clock, or divide the clock by 1.5, 2, 2.5, 3, 4, 5, 8, or 16. It has six outputs.

The DLL also operates as a clock mirror. By driving the output from a DLL off-chip and then back on again, the DLL can be used to deskew a board level clock among multiple Spartan-II devices.

In order to guarantee that the system clock is operating correctly prior to the FPGA starting up after configuration, the DLL can delay the completion of the configuration process until after it has achieved lock.

## **Boundary Scan**

Spartan-II devices support all the mandatory boundary-scan instructions specified in the IEEE standard 1149.1. A Test Access Port (TAP) and registers are provided that implement the EXTEST, SAMPLE/PRELOAD, and BYPASS instructions. The TAP also supports two USERCODE instructions and internal scan chains.

The TAP uses dedicated package pins that always operate using LVTTL. For TDO to operate using LVTTL, the V<sub>CCO</sub> for Bank 2 must be 3.3V. Otherwise, TDO switches rail-to-rail between ground and V<sub>CCO</sub>.

Boundary-scan operation is independent of individual IOB configurations, and unaffected by package type. All IOBs, including unbonded ones, are treated as independent 3-state bidirectional pins in a single scan chain. Retention of the bidirectional test capability after configuration facilitates the testing of external interconnections.

Table 6 lists the boundary-scan instructions supported in Spartan-II FPGAs. Internal signals can be captured during EXTEST by connecting them to unbonded or unused IOBs. They may also be connected to the unused outputs of IOBs defined as unidirectional input pins. This technique partially compensates for the absence of INTEST support.

#### Table 6: Boundary-Scan Instructions

Boundary-Scan Command	Binary Code[4:0]	Description
EXTEST	00000	Enables boundary-scan EXTEST operation
SAMPLE	00001	Enables boundary-scan SAMPLE operation
USR1	00010	Access user-defined register 1
USR2	00011	Access user-defined register 2
CFG_OUT	00100	Access the configuration bus for Readback
CFG_IN	00101	Access the configuration bus for Configuration
INTEST	00111	Enables boundary-scan INTEST operation
USRCODE	01000	Enables shifting out USER code
IDCODE	01001	Enables shifting out of ID Code
HIZ	01010	Disables output pins while enabling the Bypass Register
JSTART	01100	Clock the start-up sequence when StartupClk is TCK
BYPASS	11111	Enables BYPASS
RESERVED	All other codes	Xilinx reserved instructions

The public boundary-scan instructions are available prior to configuration. After configuration, the public instructions remain available together with any USERCODE instructions installed during the configuration. While the SAMPLE and BYPASS instructions are available during configuration, it is recommended that boundary-scan operations not be performed during this transitional period.

In addition to the test instructions outlined above, the boundary-scan circuitry can be used to configure the FPGA, and also to read back the configuration data.

To facilitate internal scan chains, the User Register provides three outputs (Reset, Update, and Shift) that represent the corresponding states in the boundary-scan internal state machine.

Figure 8 is a diagram of the Spartan-II family boundary scan logic. It includes three bits of Data Register per IOB, the IEEE 1149.1 Test Access Port controller, and the Instruction Register with decodes.



Figure 8: Spartan-II Family Boundary Scan Logic

## **Bit Sequence**

The bit sequence within each IOB is: In, Out, 3-State. The input-only pins contribute only the In bit to the boundary scan I/O data register, while the output-only pins contributes all three bits.

From a cavity-up view of the chip (as shown in the FPGA Editor), starting in the upper right chip corner, the boundary scan data-register bits are ordered as shown in Figure 9.

BSDL (Boundary Scan Description Language) files for Spartan-II family devices are available on the Xilinx website, in the File Download area.

Bit 0 ( TDO end) Bit 1 Bit 2	TDO.T TDO.O { Top-edge IOBs (Right to Left) { Left-edge IOBs (Top to Bottom)
	MODE.I
	Bottom-edge IOBs (Left to Right)
	Right-edge IOBs (Bottom to Top)
(TDI end)	BSCANT.UPD

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Figure 9: Boundary Scan Bit Sequence

## **Development System**

Spartan-II FPGAs are supported by the Xilinx Foundation and Alliance CAE tools. The basic methodology for Spartan-II design consists of three interrelated steps: design entry, implementation, and verification. Industry-standard tools are used for design entry and simulation (for example, Synopsys FPGA Express), while Xilinx provides proprietary architecture-specific tools for implementation.

The Xilinx development system is integrated under the Xilinx Design Manager software, providing designers with a common user interface regardless of their choice of entry and verification tools. The software simplifies the selection of implementation options with pull-down menus and on-line help.

Application programs ranging from schematic capture to Placement and Routing (PAR) can be accessed through the software. The program command sequence is generated prior to execution, and stored for documentation.

Several advanced software features facilitate Spartan-II design. Relationally-Placed Macros (RPMs), for example, are schematic-based macros with relative location constraints to guide their placement. They help ensure optimal implementation of common functions.

For HDL design entry, the Xilinx FPGA development system provides interfaces to several synthesis design environments.

A standard interface-file specification, Electronic Design Interchange Format (EDIF), simplifies file transfers into and out of the development system.

Spartan-II FPGAs supported by a unified library of standard functions. This library contains over 400 primitives and macros, ranging from 2-input AND gates to 16-bit accumulators, and includes arithmetic functions, comparators, counters, data registers, decoders, encoders, I/O functions, latches,

Boolean functions, multiplexers, shift registers, and barrel shifters.

The "soft macro" portion of the library contains detailed descriptions of common logic functions, but does not contain any partitioning or placement information. The performance of these macros depends, therefore, on the partitioning and placement obtained during implementation.

RPMs, on the other hand, do contain predetermined partitioning and placement information that permits optimal implementation of these functions. Users can create their own library of soft macros or RPMs based on the macros and primitives in the standard library.

The design environment supports hierarchical design entry, with high-level schematics that comprise major functional blocks, while lower-level schematics define the logic in these blocks. These hierarchical design elements are automatically combined by the implementation tools. Different design entry tools can be combined within a hierarchical design, thus allowing the most convenient entry method to be used for each portion of the design.

## **Design Implementation**

The place-and-route tools (PAR) automatically provide the implementation flow described in this section. The partitioner takes the EDIF netlist for the design and maps the logic into the architectural resources of the FPGA (CLBs and IOBs, for example). The placer then determines the best locations for these blocks based on their interconnections and the desired performance. Finally, the router interconnects the blocks.

The PAR algorithms support fully automatic implementation of most designs. For demanding applications, however, the user can exercise various degrees of control over the process. User partitioning, placement, and routing information is optionally specified during the design-entry process. The implementation of highly structured designs can benefit greatly from basic floorplanning.

The implementation software incorporates Timing Wizard<sup>®</sup> timing-driven placement and routing. Designers specify timing requirements along entire paths during design entry. The timing path analysis routines in PAR then recognize these user-specified requirements and accommodate them.

Timing requirements are entered on a schematic in a form directly relating to the system requirements, such as the targeted clock frequency, or the maximum allowable delay between two registers. In this way, the overall performance of the system along entire signal paths is automatically tailored to user-generated specifications. Specific timing information for individual nets is unnecessary.

## **Design Verification**

In addition to conventional software simulation, FPGA users can use in-circuit debugging techniques. Because Xilinx devices are infinitely reprogrammable, designs can be verified in real time without the need for extensive sets of software simulation vectors.

The development system supports both software simulation and in-circuit debugging techniques. For simulation, the system extracts the post-layout timing information from the design database, and back-annotates this information into the netlist for use by the simulator. Alternatively, the user can verify timing-critical portions of the design using the static timing analyzer.

For in-circuit debugging, the development system includes a download and readback cable, which connects the FPGA in the target system to a PC or workstation. After downloading the design into the FPGA, the designer can single-step the logic, readback the contents of the flip-flops, and so observe the internal logic state. Simple modifications can be downloaded into the system in a matter of minutes.

# Configuration

Configuration is the process by which the bitstream of a design, as generated by the Xilinx development software, is loaded into the internal configuration memory of the FPGA. Spartan-II devices support both serial configuration, using the master/slave serial and JTAG modes, as well as byte-wide configuration employing the Slave Parallel mode.

## **Configuration File**

Spartan-II devices are configured by sequentially loading frames of data that have been concatenated into a configuration file. Table 7 shows how much nonvolatile storage space is needed for Spartan-II devices.

It is important to note that, while a PROM is commonly used to store configuration data before loading them into the FPGA, it is by no means required. Any of a number of different kinds of under populated nonvolatile storage already available either on or off the board (i.e., hard drives, FLASH cards, etc.) can be used. For more information on configuration without a PROM, refer to <u>XAPP098</u>, *The Low-Cost*, *Efficient Serial Configuration of Spartan FPGAs*.

Table	7:	Spartan-II	Configuration	File Size
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Device	Configuration File Size (Bits)
XC2S15	197,696
XC2S30	336,768
XC2S50	559,200
XC2S100	781,216
XC2S150	1,040,096
XC2S200	1,335,840

#### Modes

Spartan-II devices support the following four configuration modes:

- Slave Serial mode
- Master Serial mode
- Slave Parallel mode
- Boundary-scan mode

The Configuration mode pins (M2, M1, M0) select among these configuration modes with the option in each case of having the IOB pins either pulled up or left floating prior to configuration. The selection codes are listed in Table 8.

Configuration through the boundary-scan port is always available, independent of the mode selection. Selecting the boundary-scan mode simply turns off the other modes. The three mode pins have internal pull-up resistors, and default to a logic High if left unconnected.

Configuration Mode	Preconfiguration Pull-ups	мо	M1	M2	CCLK Direction	Data Width	Serial D <sub>OUT</sub>
Master Serial mode	No	0	0	0	Out	1	Yes
	Yes	0	0	1			
Slave Parallel mode	Yes	0	1	0	In	8	No
	No	0	1	1			
Boundary-Scan mode	Yes	1	0	0	N/A	1	No
	No	1	0	1			
Slave Serial mode	Yes	1	1	0	In	1	Yes
	No	1	1	1			

#### Table 8: Configuration Modes

## Signals

There are two kinds of pins that are used to configure Spartan-II devices: Dedicated pins perform only specific configuration-related functions; the other pins can serve as general purpose I/Os once user operation has begun.

The dedicated pins comprise the mode pins (M2, M1, M0), the configuration clock pin (CCLK), the PROGRAM pin, the DONE pin and the boundary-scan pins (TDI, TDO, TMS, TCK). Depending on the selected configuration mode, CCLK may be an output generated by the FPGA, or may be generated externally, and provided to the FPGA as an input.

Note that some configuration pins can act as outputs. For correct operation, these pins require a V<sub>CCO</sub> of 3.3V to drive an LVTTL signal. All the relevant pins fall in banks 2 or 3.

For a more detailed description than that given below, see DS001-4, Spartan-II 2.5V FPGA Family: Pinout Tables and XAPP176, Spartan-II FPGA Series Configuration and Readback.

## The Process

The sequence of steps necessary to configure Spartan-II devices are shown in Figure 10. The overall flow can be divided into three different phases.

- Initiating Configuration
- Configuration memory clear
- Loading data frames
- Start-up

The memory clearing and start-up phases are the same for all configuration modes; however, the steps for the loading of data frames are different. Thus, the details for data frame loading are described separately in the sections devoted to each mode.

## Initiating Configuration

There are two different ways to initiate the configuration process: applying power to the device or asserting the PRO-GRAM input.

Configuration on power-up occurs automatically unless it is delayed by the user, as described in a separate section below. The waveform for configuration on power-up is shown in Figure 11, page 13. Before configuration can begin,  $V_{CCO}$  Bank 2 must be greater than 1.0V. Furthermore, all  $V_{CCINT}$  power pins must be connected to a 2.5V supply. For more information on delaying configuration, see **Clearing Configuration Memory**, page 13.

Once in user operation, the device can be re-configured simply by pulling the PROGRAM pin Low. The device acknowledges the beginning of the configuration process by driving DONE Low, then enters the memory-clearing phase.



Figure 10: Configuration Flow Diagram



#### Notes: referring to waveform above:

1. Before configuration can begin, V<sub>CCINT</sub> must be greater than 1.6V and V<sub>CCO</sub> Bank 2 must be greater than 1.0V.

#### Figure 11: Configuration Timing on Power-Up

#### **Clearing Configuration Memory**

The device indicates that clearing the configuration memory is in progress by driving INIT Low. At this time, the user can delay configuration by holding either PROGRAM or INIT Low, which causes the device to remain in the memory clearing phase. Note that the bidirectional INIT line is driving a Low logic level during memory clearing. Thus, to avoid contention, use an open-drain driver to keep INIT Low.

With no delay in force, the device indicates that the memory is completely clear by driving INIT High. The FPGA samples its mode pins on this Low-to-High transition.

#### Loading Configuration Data

Once INIT is High, the user can begin loading configuration data frames into the device. The details of loading the configuration data are discussed in the sections treating the configuration modes individually. The sequence of operations necessary to load configuration data using the serial modes is shown in Figure 13. Loading data using the Slave Parallel mode is shown in Figure 18, page 18.

#### **CRC Error Checking**

During the loading of configuration data, a CRC value embedded in the configuration file is checked against a CRC value calculated within the FPGA. If the CRC values do not match, the FPGA drives INIT Low to indicate that a frame error has occurred and configuration is aborted.

To reconfigure the device, the **PROGRAM** pin should be asserted to reset the configuration logic. Recycling power also resets the FPGA for configuration. See **Clearing Configuration Memory**.

#### Start-up

The start-up sequence oversees the transition of the FPGA from the configuration state to full user operation. A match of CRC values, indicating a successful loading of the configuration data, initiates the sequence.

During start-up, the device performs four operations:

- 1. The assertion of DONE. The failure of DONE to go High may indicate the unsuccessful loading of configuration data.
- 2. The release of the Global Three State. This activates all the I/Os.
- 3. Negates Global Set Reset (GSR). This allows all flip-flops to change state.
- 4. The assertion of Global Write Enable (GWE). This allows all RAMs and flip-flops to change state.

By default, these operations are synchronized to CCLK. The entire start-up sequence lasts eight cycles, called C0-C7, after which the loaded design is fully functional. The default timing for start-up is shown in the top half of Figure 12. The four operations can be selected to switch on any CCLK cycle C1-C6 through settings in the Xilinx Development Software. Heavy lines show default settings.

The bottom half of Figure 12 shows another commonly used version of the start-up timing known as Sync-to-DONE. This version makes the GTS, GSR, and GWE events conditional upon the DONE pin going High. This timing is important for a daisy chain of multiple FPGAs in serial mode, since it ensures that all FPGAs go through start-up together, after all their DONE pins have gone High.

Sync-to-DONE timing is selected by setting the GTS, GSR, and GWE cycles to a value of DONE in the configuration options. This causes these signals to transition one clock cycle after DONE externally transitions High.





## **Serial Modes**

There are two serial configuration modes: In Master Serial mode, the FPGA controls the configuration process by driving CCLK as an output. In Slave Serial mode, the FPGA passively receives CCLK as an input from an external agent (e.g., a microprocessor, CPLD, or second FPGA in master mode) that is controlling the configuration process. In both modes, the FPGA is configured by loading one bit per CCLK cycle. The MSB of each configuration data byte is always written to the DIN pin first.

See Figure 13 for the sequence for loading data into the Spartan-II FPGA serially. This is an expansion of the "Load Configuration Data Frames" block in Figure 10, page 12.



Figure 13: Loading Serial Mode Configuration Data

#### Slave Serial Mode

In Slave Serial mode, the FPGAs CCLK pin is driven by an external source, allowing FPGAs to be configured from other logic devices such as microprocessors or in a daisy-chain configuration. Figure 14 shows connections for a Master Serial FPGA configuring a Slave Serial FPGA from a PROM. A Spartan-II device in slave serial mode should be connected as shown for the third device from the left. Slave Serial mode is selected by a <11x> on the mode pins (M0, M1, M2).

Figure 15 shows the timing for Slave Serial configuration. The serial bitstream must be setup at the DIN input pin a short time before each rising edge of an externally generated CCLK. Multiple FPGAs in Slave Serial mode can be daisy-chained for configuration from a single source. After an FPGA is configured, data for the next device is routed to the DOUT pin. Data on the DOUT pin changes on the rising edge of CCLK. Configuration must be delayed until INIT pins of all daisy-chained FPGAs are High. For more information, see **Start-up**, page 13.



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#### Notes:

1. If the DriveDone configuration option is not active for any of the FPGAs, pull up DONE with a 3.3K  $\Omega$  resistor.

Figure 14: Master/Slave Serial Configuration Circuit Diagram



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Symbol		Description		Units
T <sub>DCC</sub>		DIN setup	5	ns, min
T <sub>CCD</sub>		DIN hold	0	ns, min
T <sub>CCO</sub>	CCLK	DOUT	12	ns, max
Т <sub>ССН</sub>	COLK	High time	5	ns, min
T <sub>CCL</sub>		Low time	5	ns, min
F <sub>CC</sub>		Maximum frequency	66	MHz, max

Figure 15: Slave Serial Mode Timing

## Master Serial Mode

In Master Serial mode, the CCLK output of the FPGA drives a Xilinx PROM which feeds a serial stream of configuration data to the FPGA's DIN input. Figure 14 shows a Master Serial FPGA configuring a Slave Serial FPGA from a PROM. A Spartan-II device in Master Serial mode should be connected as shown for the device on the left side. Master Serial mode is selected by a <00x> on the mode pins (M0, M1, M2). The PROM RESET pin is driven by INIT, and CE input is driven by DONE. The interface is identical to the slave serial mode except that an oscillator internal to the FPGA is used to generate the configuration clock (CCLK). Any of a number of different frequencies ranging from 4 to 60 MHz can be set using the ConfigRate option in the Xilinx development software. On power-up, while the first 60 bytes of the configuration data are being loaded, the CCLK frequency is always 2.5 MHz. This frequency is used until the ConfigRate bits, part of the configuration file, have been loaded into the FPGA, at which point, the frequency changes to the selected ConfigRate. Unless a different frequency is specified in the design, the default ConfigRate is 4 MHz. The period of the CCLK signal created by the internal oscillator has a variance of +45%, -30% from the specified value.

Figure 16 shows the timing for Master Serial configuration. The FPGA accepts one bit of configuration data on each rising CCLK edge. After the FPGA has been loaded, the data for the next device in a daisy-chain is presented on the DOUT pin after the rising CCLK edge.



Figure 16: Master Serial Mode Timing

## **Slave Parallel Mode**

The Slave Parallel mode is the fastest configuration option. Byte-wide data is written into the FPGA. A BUSY flag is provided for controlling the flow of data at a clock frequency  $F_{CCNH}$  above 50 MHz.

Figure 17, page 17 shows the connections for two Spartan-II devices using the Slave Parallel mode. Slave Parallel mode is selected by a <011> on the mode pins (M0, M1, M2).

The agent controlling configuration is not shown. Typically, a processor, a microcontroller, or CPLD controls the Slave Parallel interface. The controlling agent provides byte-wide configuration data, CCLK, a Chip Select ( $\overline{CS}$ ) signal and a Write signal ( $\overline{WRITE}$ ). If BUSY is asserted (High) by the FPGA, the data must be held until BUSY goes Low.

After configuration, the pins of the Slave Parallel port (D0-D7) can be used as additional user I/O. Alternatively, the port may be retained to permit high-speed 8-bit readback. Then data can be read by de-asserting WRITE. See **Readback**, page 18.



Figure 17: Slave Parallel Configuration Circuit Diagram

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Multiple Spartan-II FPGAs can be configured using the Slave Parallel mode, and be made to start-up simultaneously. To configure multiple devices in this way, wire the individual CCLK, Data, WRITE, and BUSY pins of all the devices in parallel. The individual devices are loaded separately by asserting the CS pin of each device in turn and writing the appropriate data. Sync-to-DONE start-up timing is used to ensure that the start-up sequence does not begin until all the FPGAs have been loaded. See **Start-up**, page 13.

## Write

When using the Slave Parallel Mode, write operations send packets of byte-wide configuration data into the FPGA. Figure 18, page 18 shows a flowchart of the write sequence used to load data into the Spartan-II FPGA. This is an expansion of the "Load Configuration Data Frames" block in Figure 10, page 12. The timing for write operations is shown in Figure 19, page 19. For the present example, the user holds  $\overline{WRITE}$  and  $\overline{CS}$  Low throughout the sequence of write operations. Note that when  $\overline{CS}$  is asserted on successive CCLKs,  $\overline{WRITE}$  must remain either asserted or de-asserted. Otherwise an abort will be initiated, as in the next section.

- 1. Drive data onto D0-D7. Note that to avoid contention, the data source should not be enabled while  $\overline{CS}$  is Low and  $\overline{WRITE}$  is High. Similarly, while  $\overline{WRITE}$  is High, no more than one device's  $\overline{CS}$  should be asserted.
- 2. On the rising edge of CCLK: If BUSY is Low, the data is accepted on this clock. If BUSY is High (from a previous write), the data is not accepted. Acceptance will instead occur on the first clock after BUSY goes Low, and the data must be held until this happens.
- 3. Repeat steps 2 and 3 until all the data has been sent.
- 4. De-assert  $\overline{\text{CS}}$  and  $\overline{\text{WRITE}}$ .

If CCLK is slower than  $F_{CCNH}$ , the FPGA will never assert BUSY. In this case, the above handshake is unnecessary, and data can simply be entered into the FPGA every CCLK cycle.



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#### Figure 18: Loading Configuration Data for the Slave Parallel Mode

A configuration packet does not have to be written in one continuous stretch, rather it can be split into many write sequences. Each sequence would involve assertion of  $\overline{CS}$ .

In applications where multiple clock cycles may be required to access the configuration data before each byte can be loaded into the Slave Parallel interface, a new byte of data may not be ready for each consecutive CCLK edge. In such a case the  $\overline{CS}$  signal may be de-asserted until the next byte is valid on D0-D7. While  $\overline{CS}$  is High, the Slave Parallel interface does not expect any data and ignores all CCLK transitions. However, to avoid aborting configuration, WRITE must continue to be asserted while  $\overline{CS}$  is asserted.

#### Abort

To abort configuration during a write sequence, de-assert WRITE while holding CS Low. The abort operation is initiated at the rising edge of CCLK, as shown in Figure 20, page 19. The device will remain BUSY until the aborted operation is complete. After aborting configuration, data is assumed to be unaligned to word boundaries and the FPGA requires a new synchronization word prior to accepting any new packets.

#### **Boundary-Scan Mode**

In the boundary-scan mode, no nondedicated pins are required, configuration being done entirely through the IEEE 1149.1 Test Access Port.

Configuration through the TAP uses the special CFG\_IN instruction. This instruction allows data input on TDI to be converted into data packets for the internal configuration bus.

The following steps are required to configure the FPGA through the boundary-scan port.

- 1. Load the CFG\_IN instruction into the boundary-scan instruction register (IR)
- 2. Enter the Shift-DR (SDR) state
- 3. Shift a standard configuration bitstream into TDI
- 4. Return to Run-Test-Idle (RTI)
- 5. Load the JSTART instruction into IR
- 6. Enter the SDR state
- 7. Clock TCK through the sequence (the length is programmable)
- 8. Return to RTI

Configuration and readback via the TAP is always available. The boundary-scan mode simply locks out the other modes. The boundary-scan mode is selected by a <10x> on the mode pins (M0, M1, M2).

## Readback

The configuration data stored in the Spartan-II configuration memory can be readback for verification. Along with the configuration data it is possible to readback the contents of all flip-flops/latches, LUT RAMs, and block RAMs. This capability is used for real-time debugging.

For more detailed information see XAPP176, Spartan-II FPGA Family Configuration and Readback.



Figure 19: Slave Parallel Write Timing



Figure 20: Slave Parallel Write Abort Waveforms

## **Design Considerations**

This section contains more detailed design information on the following features:

- Delay-Locked Loop . . . see page 20
- Block RAM . . . see page 24
- Versatile I/O . . . see page 29

## Using Delay-Locked Loops

The Spartan-II FPGA family provides up to four fully digital dedicated on-chip Delay-Locked Loop (DLL) circuits which provide zero propagation delay, low clock skew between output clock signals distributed throughout the device, and advanced clock domain control. These dedicated DLLs can be used to implement several circuits which improve and simplify system level design.

## Introduction

As FPGAs grow in size, quality on-chip clock distribution becomes increasingly important. Clock skew and clock delay impact device performance and the task of managing clock skew and clock delay with conventional clock trees becomes more difficult in large devices. The Spartan-II family of devices resolve this potential problem by providing up to four fully digital dedicated on-chip Delay-Locked Loop (DLL) circuits which provide zero propagation delay and low clock skew between output clock signals distributed throughout the device.

Each DLL can drive up to two global clock routing networks within the device. The global clock distribution network minimizes clock skews due to loading differences. By monitoring a sample of the DLL output clock, the DLL can compensate for the delay on the routing network, effectively eliminating the delay from the external input port to the individual clock loads within the device.

In addition to providing zero delay with respect to a user source clock, the DLL can provide multiple phases of the source clock. The DLL can also act as a clock doubler or it can divide the user source clock by up to 16.

Clock multiplication gives the designer a number of design alternatives. For instance, a 50 MHz source clock doubled by the DLL can drive an FPGA design operating at 100 MHz. This technique can simplify board design because the clock path on the board no longer distributes such a high-speed signal. A multiplied clock also provides designers the option of time-domain-multiplexing, using one circuit twice per clock cycle, consuming less area than two copies of the same circuit. Two DLLs in can be connected in series to increase the effective clock multiplication factor to four.

The DLL can also act as a clock mirror. By driving the DLL output off-chip and then back in again, the DLL can be used to de-skew a board level clock between multiple devices.

In order to guarantee the system clock establishes prior to the device "waking up," the DLL can delay the completion of the device configuration process until after the DLL achieves lock.

By taking advantage of the DLL to remove on-chip clock delay, the designer can greatly simplify and improve system level design involving high-fanout, high-performance clocks.

## Library DLL Symbols

Figure 21 shows the simplified Xilinx library DLL macro symbol, BUFGDLL. This macro delivers a quick and efficient way to provide a system clock with zero propagation delay throughout the device. Figure 22 and Figure 23 show the two library DLL primitives. These symbols provide access to the complete set of DLL features when implementing more complex applications.



Figure 21: Simplified DLL Macro Symbol BUFGDLL



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Figure 22: Standard DLL Symbol CLKDLL



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Figure 23: High-Frequency DLL Symbol CLKDLLHF

## **BUFGDLL Pin Descriptions**

Use the BUFGDLL macro as the simplest way to provide zero propagation delay for a high-fanout on-chip clock from an external input. This macro uses the IBUFG, CLKDLL and BUFG primitives to implement the most basic DLL application as shown in Figure 24.



Figure 24: BUFGDLL Schematic

This symbol does not provide access to the advanced clock domain controls or to the clock multiplication or clock division features of the DLL. This symbol also does not provide access to the RST, or LOCKED pins of the DLL. For access to these features, a designer must use the library DLL primitives described in the following sections.

#### Source Clock Input — I

The I pin provides the user source clock, the clock signal on which the DLL operates, to the BUFGDLL. For the BUF-GDLL macro the source clock frequency must fall in the low frequency range as specified in the data sheet. The BUF-GDLL requires an external signal source clock. Therefore, only an external input port can source the signal that drives the BUFGDLL I pin.

#### Clock Output — O

The clock output pin O represents a delay-compensated version of the source clock (I) signal. This signal, sourced by a global clock buffer BUFG symbol, takes advantage of the dedicated global clock routing resources of the device.

The output clock has a 50/50 duty cycle unless you deactivate the duty cycle correction property.

## **CLKDLL Primitive Pin Descriptions**

The library CLKDLL primitives provide access to the complete set of DLL features needed when implementing more complex applications with the DLL.

#### Source Clock Input — CLKIN

The CLKIN pin provides the user source clock (the clock signal on which the DLL operates) to the DLL. The CLKIN frequency must fall in the ranges specified in the data sheet. A global clock buffer (BUFG) driven from another CLKDLL

or one of the global clock input buffers (IBUFG) must source this clock signal.

#### Feedback Clock Input — CLKFB

The DLL requires a reference or feedback signal to provide the delay-compensated output. Connect only the CLK0 or CLK2X DLL outputs to the feedback clock input (CLKFB) pin to provide the necessary feedback to the DLL. The feedback clock input can also be provided through one of the following pin.

IBUFG - Global Clock Input Pad

If an IBUFG sources the CLKFB pin, the following special rules apply.

- 1. An external input port must source the signal that drives the IBUFG I pin.
- The CLK2X output must feed back to the device if both the CLK0 and CLK2X outputs are driving off chip devices.
- 3. That signal must directly drive only OBUFs and nothing else.

These rules enable the software determine which DLL clock output sources the CLKFB pin.

#### Reset Input — RST

When the reset pin RST activates the LOCKED signal deactivates within four source clock cycles. The RST pin, active High, must either connect to a dynamic signal or tied to ground. As the DLL delay taps reset to zero, glitches can occur on the DLL clock output pins. Activation of the RST pin can also severely affect the duty cycle of the clock output pins. Furthermore, the DLL output clocks no longer deskew with respect to one another. For these reasons, rarely use the reset pin unless re-configuring the device or changing the input frequency.

## 2x Clock Output — CLK2X

The output pin CLK2X provides a frequency-doubled clock with an automatic 50/50 duty-cycle correction. Until the CLKDLL has achieved lock, the CLK2X output appears as a 1x version of the input clock with a 25/75 duty cycle. This behavior allows the DLL to lock on the correct edge with respect to source clock. This pin is not available on the CLKDLLHF primitive.

## Clock Divide Output — CLKDV

The clock divide output pin CLKDV provides a lower frequency version of the source clock. The CLKDV\_DIVIDE property controls CLKDV such that the source clock is divided by N where N is either 1.5, 2, 2.5, 3, 4, 5, 8, or 16.

This feature provides automatic duty cycle correction such that the CLKDV output pin always has a 50/50 duty cycle.

#### 1x Clock Outputs — CLK[0/90/180/270]

The 1x clock output pin CLK0 represents a delay-compensated version of the source clock (CLKIN) signal. The CLKDLL primitive provides three phase-shifted versions of the CLK0 signal while CLKDLLHF provides only the 180 phase-shifted version. The relationship between phase shift and the corresponding period shift appears in Table 9.

The timing diagrams in Figure 25 illustrate the DLL clock output characteristics.

# Table 9: Relationship of Phase-Shifted Output Clock toPeriod Shift

Phase (degrees)	Period Shift (percent)
0	0%
90	25%
180	50%
270	75%

The DLL provides duty cycle correction on all 1x clock outputs such that all 1x clock outputs by default have a 50/50 duty cycle. The DUTY\_CYCLE\_CORRECTION property (TRUE by default), controls this feature. In order to deactivate the DLL duty cycle correction, attach the DUTY\_CYCLE\_CORRECTION=FALSE property to the DLL symbol. When duty cycle correction deactivates, the output clock has the same duty cycle as the source clock.

The DLL clock outputs can drive an OBUF, a BUFG, or they can route directly to destination clock pins. The DLL clock outputs can only drive the BUFGs that reside on the same edge (top or bottom).

#### Locked Output — LOCKED

In order to achieve lock, the DLL may need to sample several thousand clock cycles. After the DLL achieves lock the LOCKED signal activates. The DLL timing parameter section of the data sheet provides estimates for locking times.

In order to guarantee that the system clock is established prior to the device "waking up," the DLL can delay the completion of the device configuration process until after the DLL locks. The STARTUP\_WAIT property activates this feature.

Until the LOCKED signal activates, the DLL output clocks are not valid and can exhibit glitches, spikes, or other spurious movement. In particular the CLK2X output will appear as a 1x clock with a 25/75 duty cycle.

#### **DLL Properties**

Properties provide access to some of the Spartan-II family DLL features, (for example, clock division and duty cycle correction).

#### **Duty Cycle Correction Property**

The 1x clock outputs, CLK0, CLK90, CLK180, and CLK270, use the duty-cycle corrected default, exhibiting a 50/50 duty cycle. The DUTY\_CYCLE\_CORRECTION property (by default TRUE) controls this feature. To deactivate the DLL

duty-cycle correction for the 1x clock outputs, attach the DUTY\_CYCLE\_CORRECTION=FALSE property to the DLL symbol. When duty-cycle correction deactivates, the output clock has the same duty cycle as the source clock.



Figure 25: DLL Output Characteristics

## **Clock Divide Property**

The CLKDV\_DIVIDE property specifies how the signal on the CLKDV pin is frequency divided with respect to the CLK0 pin. The values allowed for this property are 1.5, 2, 2.5, 3, 4, 5, 8, or 16; the default value is 2.

#### Startup Delay Property

This property, STARTUP\_WAIT, takes on a value of TRUE or FALSE (the default value). When TRUE the device configuration DONE signal waits until the DLL locks before going to High.

#### **DLL Location Constraints**

The DLLs are distributed such that there is one DLL in each corner of the device. The location constraint LOC, attached to the DLL symbol with the numeric identifier 0, 1, 2, or 3, controls DLL location. The orientation of the four DLLs and their corresponding clock resources appears in Figure 26.

#### The LOC property uses the following form.

```
LOC = DLL2
```



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#### Figure 26: Orientation of DLLs

## **Design Factors**

Use the following design considerations to avoid pitfalls and improve success designing with Xilinx devices.

#### Input Clock

The output clock signal of a DLL, essentially a delayed version of the input clock signal, reflects any instability on the input clock in the output waveform. For this reason the quality of the DLL input clock relates directly to the quality of the output clock waveforms generated by the DLL. The DLL input clock requirements are specified in the data sheet.

In most systems a crystal oscillator generates the system clock. The DLL can be used with any commercially available quartz crystal oscillator. For example, most crystal oscillators produce an output waveform with a frequency tolerance of 100 PPM, meaning 0.01 percent change in the clock period. The DLL operates reliably on an input waveform with a frequency drift of up to 1 ns — orders of magnitude in excess of that needed to support any crystal oscillator in the industry. However, the cycle-to-cycle jitter must be kept to less than 300 ps in the low frequencies and 150 ps for the high frequencies.

## Input Clock Changes

Changing the period of the input clock beyond the maximum drift amount requires a manual reset of the CLKDLL. Failure to reset the DLL will produce an unreliable lock signal and output clock.

It is possible to stop the input clock with little impact to the DLL. Stopping the clock should be limited to less than 100  $\mu$ s to keep device cooling to a minimum. The clock should be stopped during a Low phase, and when restored

the full High period should be seen. During this time LOCKED will stay High and remain High when the clock is restored.

When the clock is stopped, one to four more clocks will still be observed as the delay line is flushed. When the clock is restarted, the output clocks will not be observed for one to four clocks as the delay line is filled. The most common case will be two or three clocks.

In a similar manner, a phase shift of the input clock is also possible. The phase shift will propagate to the output one to four clocks after the original shift, with no disruption to the CLKDLL control.

#### **Output Clocks**

As mentioned earlier in the DLL pin descriptions, some restrictions apply regarding the connectivity of the output pins. The DLL clock outputs can drive an OBUF, a global clock buffer BUFG, or they can route directly to destination clock pins. The only BUFGs that the DLL clock outputs can drive are the two on the same edge of the device (top or bottom).

Do not use the DLL output clock signals until after activation of the LOCKED signal. Prior to the activation of the LOCKED signal, the DLL output clocks are not valid and can exhibit glitches, spikes, or other spurious movement.

## **Useful Application Examples**

The Spartan-II DLL can be used in a variety of creative and useful applications. The following examples show some of the more common applications.

#### Standard Usage

The circuit shown in Figure 27 resembles the BUFGDLL macro implemented to provide access to the RST and LOCKED pins of the CLKDLL.



Figure 27: Standard DLL Implementation

## Deskew of Clock and Its 2x Multiple

The circuit shown in Figure 28 implements a 2x clock multiplier and also uses the CLK0 clock output with zero ns skew between registers on the same chip. A clock divider circuit

could alternatively be implemented using similar connections.



Figure 28: DLL Deskew of Clock and 2x Multiple

Because any single DLL can only access at most two BUFGs, any additional output clock signals must be routed from the DLL in this example on the high speed backbone routing.

#### Generating a 4x Clock

By connecting two DLL circuits each implementing a 2x clock multiplier in series as shown in Figure 29, a 4x clock multiply can be implemented with zero ns skew between registers in the same device.

If other clock output is needed, the clock could access a BUFG only if the DLLs are constrained to exist on opposite edges (Top or Bottom) of the device.

When using this circuit it is vital to use the SRL16 cell to reset the second DLL after the initial chip reset. If this is not done, the second DLL may not recognize the change of frequencies from when the input changes from a 1x (25/75) waveform to a 2x (50/50) waveform.

## **Using Block RAM Features**

The Spartan-II FPGA family provides dedicated blocks of on-chip, true dual-read/write port synchronous RAM, with 4096 memory cells. Each port of the block RAM memory can be independently configured as a read/write port, a read port, a write port, and can be configured to a specific data width. The block RAM memory offers new capabilities allowing the FPGA designer to simplify designs.

## **Operating Modes**

Block RAM memory supports two operating modes.

- Read Through
- Write Back

#### Read Through (One Clock Edge)

The read address is registered on the read port clock edge and data appears on the output after the RAM access time. Some memories may place the latch/register at the outputs depending on the desire to have a faster clock-to-out versus setup time. This is generally considered to be an inferior solution since it changes the read operation to an asynchronous function with the possibility of missing an address/control line transition during the generation of the read pulse clock.



Figure 29: DLL Generation of 4x Clock

## Write Back (One Clock Edge)

The write address is registered on the write port clock edge and the data input is written to the memory and mirrored on the write port input.

## **Block RAM Characteristics**

- 1. All inputs are registered with the port clock and have a setup to clock timing specification.
- 2. All outputs have a read through or write back function depending on the state of the port WE pin. The outputs relative to the port clock are available after the clock-to-out timing specification.
- 3. The block RAM are true SRAM memories and do not have a combinatorial path from the address to the output. The LUT cells in the CLBs are still available with this function.
- 4. The ports are completely independent from each other (*i.e.*, clocking, control, address, read/write function, and data width) without arbitration.

- 5. A write operation requires only one clock edge.
- 6. A read operation requires only one clock edge.

The output ports are latched with a self timed circuit to guarantee a glitch free read. The state of the output port will not change until the port executes another read or write operation.

## **Library Primitives**

Figure 30 and Figure 31 show the two generic library block RAM primitives. Table 10 describes all of the available primitives for synthesis and simulation.



#### Figure 30: Dual-Port Block RAM Memory



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Figure 31: Single-Port Block RAM Memory

Table 10: Available Library Primitives							
Primitive	Port A Width	Port B Width					
RAMB4_S1	1	N/A					
RAMB4_S1_S1		1					
RAMB4_S1_S2		2					
RAMB4_S1_S4		4					
RAMB4_S1_S8		8					
RAMB4_S1_S16		16					
RAMB4_S2	2	N/A					
RAMB4_S2_S2		2					
RAMB4_S2_S4		4					
RAMB4_S2_S8		8					
RAMB4_S2_S16		16					
RAMB4_S4	4	N/A					
RAMB4_S4_S4		4					
RAMB4_S4_S8		8					
RAMB4_S4_S16		16					
RAMB4_S8	8	N/A					
RAMB4_S8_S8		8					
RAMB4_S8_S16		16					
RAMB4_S16	16	N/A					
RAMB4_S16_S16		16					

## **Port Signals**

Each block RAM port operates independently of the others while accessing the same set of 4096 memory cells.

Table 11 describes the depth and width aspect ratios for theblock RAM memory.

Width	Depth	ADDR Bus	Data Bus
1	4096	ADDR<11:0>	DATA<0>
2	2048	ADDR<10:0>	DATA<1:0>
4	1024	ADDR<9:0>	DATA<3:0>
8	512	ADDR<8:0>	DATA<7:0>
16	256	ADDR<7:0>	DATA<15:0>

Table 11: Block RAM Port Aspect Ratios

## Clock—CLK[A|B]

Each port is fully synchronous with independent clock pins. All port input pins have setup time referenced to the port CLK pin. The data output bus has a clock-to-out time referenced to the CLK pin.

#### Enable—EN[A/B]

The enable pin affects the read, write and reset functionality of the port. Ports with an inactive enable pin keep the output pins in the previous state and do not write data to the memory cells.

## Write Enable—WE[A/B]

Activating the write enable pin allows the port to write to the memory cells. When active, the contents of the data input bus are written to the RAM at the address pointed to by the address bus, and the new data also reflects on the data out bus. When inactive, a read operation occurs and the contents of the memory cells referenced by the address bus reflect on the data out bus.

#### Reset—RST[A|B]

The reset pin forces the data output bus latches to zero synchronously. This does not affect the memory cells of the RAM and does not disturb a write operation on the other port.

#### Address Bus—ADDR[A/B]<#:0>

The address bus selects the memory cells for read or write. The width of the port determines the required width of this bus as shown in Table 11.

#### Data In Bus-DI[A/B]<#:0>

The data in bus provides the new data value to be written into the RAM. This bus and the port have the same width, as shown in Table 11.

## Data Output Bus—DO[A/B]<#:0>

The data out bus reflects the contents of the memory cells referenced by the address bus at the last active clock edge. During a write operation, the data out bus reflects the data in bus. The width of this bus equals the width of the port. The allowed widths appear in Table 11.

## **Inverting Control Pins**

The four control pins (CLK, EN, WE and RST) for each port have independent inversion control as a configuration option.

## **Address Mapping**

Each port accesses the same set of 4096 memory cells using an addressing scheme dependent on the width of the port. The physical RAM location addressed for a particular width are described in the following formula (of interest only when the two ports use different aspect ratios).

Start = 
$$([ADDR_{port} + 1] * Width_{port}) - 1$$
  
End = ADDR<sub>port</sub> \* Width<sub>port</sub>

Table 12 shows low order address mapping for each portwidth.

Table	12:	Port	Address	Mapping
-------	-----	------	---------	---------

Port Widt h	Port Addresses																
1	4095	1 5	1 4	1 3	1 2	1 1	1 0	0 9	0 8	0 7	0 6	0 5	0 4	0 3	0 2	0 1	0 0
2	2047	07 06		06 05 04		03 02		2	01 (		0	0					
4	1023		03 02							0	1			0	0		
8	511	01 00															
16	255		00														

## **Creating Larger RAM Structures**

The block RAM columns have specialized routing to allow cascading blocks together with minimal routing delays. This achieves wider or deeper RAM structures with a smaller timing penalty than when using normal routing channels.

## **Location Constraints**

Block RAM instances can have LOC properties attached to them to constrain the placement. The block RAM placement locations are separate from the CLB location naming convention, allowing the LOC properties to transfer easily from array to array. The LOC properties use the following form:

#### LOC = RAMB4\_R#C#

RAMB4\_R0C0 is the upper left RAMB4 location on the device.

## **Conflict Resolution**

The block RAM memory is a true dual-read/write port RAM that allows simultaneous access of the same memory cell from both ports. When one port writes to a given memory cell, the other port must not address that memory cell (for a write or a read) within the clock-to-clock setup window. The following lists specifics of port and memory cell write conflict resolution.

- If both ports write to the same memory cell simultaneously, violating the clock-to-clock setup requirement, consider the data stored as invalid.
- If one port attempts a read of the same memory cell the other simultaneously writes, violating the clock-to-clock setup requirement, the following occurs.
  - The write succeeds
  - The data out on the writing port accurately reflects the data written.
  - The data out on the reading port is invalid.

Conflicts do not cause any physical damage.

#### Single Port Timing

Figure 32 shows a timing diagram for a single port of a block RAM memory. The block RAM AC switching characteristics are specified in the data sheet. The block RAM memory is initially disabled.

At the first rising edge of the CLK pin, the ADDR, DI, EN, WE, and RST pins are sampled. The EN pin is High and the WE pin is Low indicating a read operation. The DO bus contains the contents of the memory location, 0x00, as indicated by the ADDR bus.

At the second rising edge of the CLK pin, the ADDR, DI, EN, WR, and RST pins are sampled again. The EN and WE pins are High indicating a write operation. The DO bus mirrors the DI bus. The DI bus is written to the memory location 0x0F.

At the third rising edge of the CLK pin, the ADDR, DI, EN, WR, and RST pins are sampled again. The EN pin is High and the WE pin is Low indicating a read operation. The DO bus contains the contents of the memory location 0x7E as indicated by the ADDR bus.

At the fourth rising edge of the CLK pin, the ADDR, DI, EN, WR, and RST pins are sampled again. The EN pin is Low indicating that the block RAM memory is now disabled. The DO bus retains the last value.

#### **Dual Port Timing**

Figure 33 shows a timing diagram for a true dual-port read/write block RAM memory. The clock on port A has a longer period than the clock on Port B. The timing parameter  $T_{BCCS}$ , (clock-to-clock setup) is shown on this diagram. The parameter,  $T_{BCCS}$  is violated once in the diagram. All other timing parameters are identical to the single port version shown in Figure 32.

T<sub>BCCS</sub> is only of importance when the address of both ports are the same and at least one port is performing a write operation. When the clock-to-clock set-up parameter is violated for a WRITE-WRITE condition, the contents of the memory at that location will be invalid. When the clock-to-clock set-up parameter is violated for a WRITE-READ condition, the contents of the memory will be correct, but the read port will have invalid data. At the first rising edge of the CLKA, memory location 0x00 is to be written with the value 0xAAAA and is mirrored on the DOA bus. The last operation of Port B was a read to the same memory location 0x00. The DOB bus of Port B does not change with the new value on Port A, and retains the last read value. A short time later, Port B executes another read to memory location 0x00, and the DOB bus now reflects the new memory value written by Port A.

At the second rising edge of CLKA, memory location 0x7E is written with the value 0x9999 and is mirrored on the DOA bus. Port B then executes a read operation to the same memory location without violating the  $T_{BCCS}$  parameter and the DOB reflects the new memory values written by Port A.



Figure 32: Timing Diagram for Single-Port Block RAM Memory



Figure 33: Timing Diagram for a True Dual-Port Read/Write Block RAM Memory

At the third rising edge of CLKA, the  $T_{BCCS}$  parameter is violated with two writes to memory location 0x0F. The DOA and DOB busses reflect the contents of the DIA and DIB busses, but the stored value at 0x7E is invalid.

At the fourth rising edge of CLKA, a read operation is performed at memory location 0x0F and invalid data is present on the DOA bus. Port B also executes a read operation to memory location 0x0F and also reads invalid data.

At the fifth rising edge of CLKA a read operation is performed that does not violate the  $T_{BCCS}$  parameter to the previous write of 0x7E by Port B. THe DOA bus reflects the recently written value by Port B.

## Initialization

The block RAM memory can initialize during the device configuration sequence. The 16 initialization properties of 64 hex values each (a total of 4096 bits) set the initialization of each RAM. These properties appear in Table 13. Any initialization properties not explicitly set configure as zeros. Partial initialization strings pad with zeros. Initialization strings greater than 64 hex values generate an error. The RAMs can be simulated with the initialization values using generics in VHDL simulators and parameters in Verilog simulators.

## Initialization in VHDL and Synopsys

The block RAM structures may be initialized in VHDL for both simulation and synthesis for inclusion in the EDIF output file. The simulation of the VHDL code uses a generic to pass the initialization. Synopsys FPGA compiler does not presently support generics. The initialization values instead attach as attributes to the RAM by a built-in Synopsys dc\_script. The translate\_off statement stops synthesis translation of the generic statements. The following code illustrates a module that employs these techniques.

## Initialization in Verilog and Synopsys

The block RAM structures may be initialized in Verilog for both simulation and synthesis for inclusion in the EDIF output file. The simulation of the Verilog code uses a defparam to pass the initialization. The Synopsys FPGA compiler does not presently support defparam. The initialization values instead attach as attributes to the RAM by a built-in Synopsys dc\_script. The translate\_off statement stops synthesis translation of the defparam statements. The following code illustrates a module that employs these techniques.

## **Block Memory Generation**

The CoreGen program generates memory structures using the block RAM features. This program outputs VHDL or Verilog simulation code templates and an EDIF file for inclusion in a design.

Property	Memory Cells
INIT_00	255 to 0
INIT_01	511 to 256
INIT_02	767 to 512
INIT_03	1023 to 768
INIT_04	1279 to 1024
INIT_05	1535 to 1280
INIT_06	1791 to 1536
INIT_07	2047 to 1792
INIT_08	2303 to 2048
INIT_09	2559 to 2304
INIT_0a	2815 to 2560
INIT_0b	3071 to 2816
INIT_0c	3327 to 3072
INIT_0d	3583 to 3328
INIT_0e	3839 to 3584
INIT_0f	4095 to 3840

# Using Versatile I/O

The Spartan-II FPGA family includes a highly configurable, high-performance I/O resource called Versatile I/O to provide support for a wide variety of I/O standards. The Versatile I/O resource is a robust set of features including programmable control of output drive strength, slew rate, and input delay and hold time. Taking advantage of the flexibility and Versatile I/O features and the design considerations described in this document can improve and simplify system level design.

## Introduction

As FPGAs continue to grow in size and capacity, the larger and more complex systems designed for them demand an increased variety of I/O standards. Furthermore, as system clock speeds continue to increase, the need for high-performance I/O becomes more important. While chip-to-chip delays have an increasingly substantial impact on overall system speed, the task of achieving the desired system performance becomes more difficult with the proliferation of low-voltage I/O standards. Versatile I/O, the revolutionary input/output resources of Spartan-II devices, has resolved this potential problem by providing a highly configurable, high-performance alternative to the I/O resources of more conventional programmable devices. The Spartan-II Versatile I/O features combine the flexibility and time-to-market advantages of programmable logic with the high performance previously available only with ASICs and custom ICs.

Each Versatile I/O block can support up to 16 I/O standards. Supporting such a variety of I/O standards allows the support of a wide variety of applications, from general purpose standard applications to high-speed low-voltage memory busses.

Versatile I/O blocks also provide selectable output drive strengths and programmable slew rates for the LVTTL output buffers, as well as an optional, programmable weak pull-up, weak pull-down, or weak "keeper" circuit ideal for use in external bussing applications.

Each Input/Output Block (IOB) includes three registers, one each for the input, output, and 3-state signals within the IOB. These registers are optionally configurable as either a D-type flip-flop or as a level sensitive latch.

The input buffer has an optional delay element used to guarantee a zero hold time requirement for input signals registered within the IOB.

The Versatile I/O features also provide dedicated resources for input reference voltage ( $V_{REF}$ ) and output source voltage ( $V_{CCO}$ ), along with a convenient banking system that simplifies board design.

By taking advantage of the built-in features and wide variety of I/O standards supported by the Versatile I/O features, system-level design and board design can be greatly simplified and improved.

## **Fundamentals**

Modern bus applications, pioneered by the largest and most influential companies in the digital electronics industry, are commonly introduced with a new I/O standard tailored specifically to the needs of that application. The bus I/O standards provide specifications to other vendors who create products designed to interface with these applications. Each standard often has its own specifications for current, voltage, I/O buffering, and termination techniques.

The ability to provide the flexibility and time-to-market advantages of programmable logic is increasingly dependent on the capability of the programmable logic device to support an ever increasing variety of I/O standards

The Versatile I/O resources feature highly configurable input and output buffers which provide support for a wide variety of I/O standards. As shown in Table 14, each buffer type can support a variety of voltage requirements. 
 Table 14:
 Versatile I/O Supported Standards (Typical Values)

valuesj			1
I/O Standard	Input Reference Voltage (V <sub>REF</sub> )	Output Source Voltage (V <sub>CCO</sub> )	Board Termination Voltage (V <sub>TT</sub> )
LVTTL (2-24 mA)	N/A	3.3	N/A
LVCMOS2	N/A	2.5	N/A
PCI (3V/5V, 33 MHz/66 MHz)	N/A	3.3	N/A
GTL	0.8	N/A	1.2
GTL+	1.0	N/A	1.5
HSTL Class I	0.75	1.5	0.75
HSTL Class III	0.9	1.5	1.5
HSTL Class IV	0.9	1.5	1.5
SSTL3 Class I and II	1.5	3.3	1.5
SSTL2 Class I and II	1.25	2.5	1.25
CTT	1.5	3.3	1.5
AGP-2X	1.32	3.3	N/A

## **Overview of Supported I/O Standards**

This section provides a brief overview of the I/O standards supported by all Spartan-II devices.

While most I/O standards specify a range of allowed voltages, this document records typical voltage values only. Detailed information on each specification may be found on the Electronic Industry Alliance Jedec website at http://www.jedec.org

#### LVTTL — Low-Voltage TTL

The Low-Voltage TTL (LVTTL) standard is a general purpose EIA/JESDSA standard for 3.3V applications that uses an LVTTL input buffer and a Push-Pull output buffer. This standard requires a 3.3V output source voltage ( $V_{CCO}$ ), but does not require the use of a reference voltage ( $V_{REF}$ ) or a termination voltage ( $V_{TT}$ ).

#### LVCMOS2 — Low-Voltage CMOS for 2.5V

The Low-Voltage CMOS for 2.5V or lower (LVCMOS2) standard is an extension of the LVCMOS standard (JESD 8.5) used for general purpose 2.5V applications. This standard requires a 2.5V output source voltage ( $V_{CCO}$ ), but does not require the use of a reference voltage ( $V_{REF}$ ) or a board termination voltage ( $V_{TT}$ ).

## PCI — Peripheral Component Interface

The Peripheral Component Interface (PCI) standard specifies support for both 33 MHz and 66 MHz PCI bus applications. It uses a LVTTL input buffer and a push-pull output buffer. This standard does not require the use of a reference voltage ( $V_{REF}$ ) or a board termination voltage ( $V_{TT}$ ), however, it does require a 3.3V output source voltage ( $V_{CCO}$ ). I/Os configured for the PCI, 33 MHz, 5V standard are also 5V-tolerant.

#### GTL — Gunning Transceiver Logic Terminated

The Gunning Transceiver Logic (GTL) standard is a high-speed bus standard (JESD8.3) invented by Xerox. Xilinx has implemented the terminated variation of this standard. This standard requires a differential amplifier input buffer and an open-drain output buffer.

#### GTL+ — Gunning Transceiver Logic Plus

The Gunning Transceiver Logic Plus (GTL+) standard is a high-speed bus standard (JESD8.3) first used by the Pentium Pro processor.

## HSTL — High-Speed Transceiver Logic

The High-Speed Transceiver Logic (HSTL) standard is a general purpose high-speed, 1.5V bus standard sponsored by IBM (EIA/JESD 8-6). This standard has four variations or classes. Versatile I/O devices support Class I, III, and IV. This standard requires a Differential Amplifier input buffer and a Push-Pull output buffer.

## SSTL3 — Stub Series Terminated Logic for 3.3V

The Stub Series Terminated Logic for 3.3V (SSTL3) standard is a general purpose 3.3V memory bus standard also sponsored by Hitachi and IBM (JESD8-8). This standard has two classes, I and II. Versatile I/O devices support both classes for the SSTL3 standard. This standard requires a Differential Amplifier input buffer and an Push-Pull output buffer.

## SSTL2 — Stub Series Terminated Logic for 2.5V

The Stub Series Terminated Logic for 2.5V (SSTL2) standard is a general purpose 2.5V memory bus standard sponsored by Hitachi and IBM (JESD8-9). This standard has two classes, I and II. Versatile I/O devices support both classes for the SSTL2 standard. This standard requires a Differential Amplifier input buffer and an Push-Pull output buffer.

## CTT — Center Tap Terminated

The Center Tap Terminated (CTT) standard is a 3.3V memory bus standard sponsored by Fujitsu (JESD8-4). This standard requires a Differential Amplifier input buffer and a Push-Pull output buffer.

#### AGP-2X — Advanced Graphics Port

The Intel AGP standard is a 3.3V Advanced Graphics Port-2X bus standard used with the Pentium II processor for

graphics applications. This standard requires a Push-Pull output buffer and a Differential Amplifier input buffer.

## Library Symbols

The Xilinx library includes an extensive list of symbols designed to provide support for the variety of Versatile I/O features. Most of these symbols represent variations of the five generic Versatile I/O symbols:

- IBUF (input buffer)
- IBUFG (global clock input buffer)
- OBUF (output buffer)
- OBUFT (3-state output buffer)
- IOBUF (input/output buffer)

#### IBUF

Signals used as inputs to the Spartan-II device must source an input buffer (IBUF) via an external input port. The generic IBUF symbol appears in Figure 34. The extension to the base name defines which I/O standard the IBUF uses. The assumed standard is LVTTL when the generic IBUF has no specified extension.



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Figure 34: Input Buffer (IBUF) Symbols

The following list details the variations of the IBUF symbol:

- IBUF
- IBUF\_LVCMOS2
- IBUF\_PCI33\_3
- IBUF\_PCI33\_5
- IBUF\_PCI66\_3
- IBUF\_GTL
- IBUF\_GTLP
- IBUF\_HSTL\_I
- IBUF\_HSTL\_III
- IBUF\_HSTL\_IV
- IBUF\_SSTL3\_I
- IBUF SSTL3 II
- IBUF\_SSTL2\_I
- IBUF SSTL2 II
- IBUF\_CTT
- IBUF\_AGP

When the IBUF symbol supports an I/O standard such as LVTTL, LVCMOS, or PCI33\_5, the IBUF automatically configures as a 5V tolerant input buffer unless the  $V_{CCO}$  for the bank is less than 2V. If the single-ended IBUF is placed in a

bank with an HSTL standard ( $V_{CCO} < 2V$ ), the input buffer is not 5V tolerant.

The voltage reference signal is "banked" within the Spartan-II device on a half-edge basis such that for all packages there are eight independent  $V_{REF}$  banks internally. See Figure 35 for a representation of the I/O banks. Within each bank approximately one of every six I/O pins is automatically configured as a  $V_{REF}$  input.

IBUF placement restrictions require that any differential amplifier input signals within a bank be of the same standard. How to specify a specific location for the IBUF via the LOC property is described below. Table 15 summarizes the input standards compatibility requirements.

An optional delay element is associated with each IBUF. When the IBUF drives a flip-flop within the IOB, the delay element by default activates to ensure a zero hold-time requirement. The NODELAY=TRUE property overrides this default.

When the IBUF does not drive a flip-flop within the IOB, the delay element de-activates by default to provide higher performance. To delay the input signal, activate the delay element with the DELAY=TRUE property.



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Figure 35: I/O Banks

# Table 15: Xilinx Input Standards CompatibilityRequirements

Rule 1	All differential amplifier input signals within a bank are required to be of the same standard.
Rule 2	There are no placement restrictions for inputs with standards that require a single-ended input buffer.

## IBUFG

Signals used as high fanout clock inputs to the Spartan-II device should drive a global clock input buffer (IBUFG) via an external input port in order to take advan-

tage of one of the four dedicated global clock distribution networks. The output of the IBUFG symbol can only drive a CLKDLL, CLKDLLHF, or a BUFG symbol. The generic IBUFG symbol appears in Figure 36.



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Figure 36: Global Clock Input Buffer (IBUFG) Symbol

The extension to the base name determines which I/O standard is used by the IBUFG. With no extension specified for the generic IBUFG symbol, the assumed standard is LVTTL.

The following list details variations of the IBUFG symbol.

- IBUFG
- IBUFG\_LVCMOS2
- IBUFG\_PCI33\_3
- IBUFG\_PCI33\_5
- IBUFG\_PCI66\_3
- IBUFG GTL
- IBUFG\_GTLP
- IBUFG\_HSTL\_I
- IBUFG\_HSTL\_III
- IBUFG\_HSTL\_IV
- IBUFG\_SSTL3\_I
- IBUFG\_SSTL3\_II
- IBUFG\_SSTL2\_I
- IBUFG\_SSTL2\_II
- IBUFG\_CTT
- IBUFG\_AGP

The voltage reference signal is "banked" within the Spartan-II device on a half-edge basis such that for all packages there are eight independent  $V_{REF}$  banks internally. See Figure 35 for a representation of the I/O banks. Within each bank approximately one of every six I/O pins is automatically configured as a  $V_{RFF}$  input.

IBUFG placement restrictions require any differential amplifier input signals within a bank be of the same standard. The LOC property can specify a location for the IBUFG.

As an added convenience, the BUFGP can be used to instantiate a high fanout clock input. The BUFGP symbol represents a combination of the LVTTL IBUFG and BUFG symbols, such that the output of the BUFGP can connect directly to the clock pins throughout the design.

The Spartan-II BUFGP symbol can only be placed in a global clock pad location. The LOC property can specify a location for the BUFGP.

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## OBUF

An OBUF must drive outputs through an external output port. The generic output buffer (OBUF) symbol appears in Figure 37.



DS001\_38\_061200

Figure 37: Output Buffer (OBUF) Symbol

The extension to the base name defines which I/O standard the OBUF uses. With no extension specified for the generic OBUF symbol, the assumed standard is slew rate limited LVTTL with 12 mA drive strength.

The LVTTL OBUF additionally can support one of two slew rate modes to minimize bus transients. By default, the slew rate for each output buffer is reduced to minimize power bus transients when switching non-critical signals.

LVTTL output buffers have selectable drive strengths.

The format for LVTTL OBUF symbol names is as follows.

OBUF\_<slew\_rate>\_<drive\_strength>

<slew\_rate> is either F (Fast), or S (Slow) and <drive\_strength> is specified in milliamps (2, 4, 6, 8, 12, 16, or 24).

The following list details variations of the OBUF symbol.

- OBUF
- OBUF\_S\_2
- OBUF\_S\_4
- OBUF\_S\_6
- OBUF\_S\_8
- OBUF\_S\_12
- OBUF\_S\_16
- OBUF\_S\_24
- OBUF\_F\_2
- OBUF\_F\_4
- OBUF\_F\_6
- OBUF\_F\_8
- OBUF\_F\_12
- OBUF\_F\_16
- OBUF\_F\_24
- OBUF\_LVCMOS2
- OBUF\_PCI33\_3
- OBUF\_PCI33\_5
- OBUF\_PCI66\_3

- OBUF\_GTL
- OBUF\_GTLP
- OBUF\_HSTL\_I
- OBUF\_HSTL\_III
- OBUF\_HSTL\_IV
- OBUF\_SSTL3\_I
- OBUF\_SSTL3\_II
- OBUF\_SSTL2\_I
- OBUF\_SSTL2\_II
- OBUF\_CTT
- OBUF\_AGP

OBUF placement restrictions require that within a given  $V_{CCO}$  bank each OBUF share the same output source drive voltage. Input buffers of any type and output buffers that do not require  $V_{CCO}$  can be placed within any  $V_{CCO}$  bank. Table 16 summarizes the output compatibility requirements. The LOC property can specify a location for the OBUF.

# Table 16: Output Standards CompatibilityRequirements

Rule 1	Only outputs with standards which share compatible $\rm V_{\rm CCO}$ may be used within the same bank.
Rule 2	There are no placement restrictions for outputs with standards that do not require a $V_{\mbox{CCO}}.$
V <sub>CCO</sub>	Compatible Standards
3.3	LVTTL, SSTL3_I, SSTL3_II, CTT, AGP, GTL, GTL+, PCI33_3, PCI66_3
2.5	SSTL2_I, SSTL2_II, LVCMOS2, GTL, GTL+
1.5	HSTL_I, HSTL_III, HSTL_IV, GTL, GTL+

#### OBUFT

The generic 3-state output buffer OBUFT, shown in Figure 38, typically implements 3-state outputs or bidirectional I/O.

The extension to the base name defines which I/O standard OBUFT uses. With no extension specified for the generic OBUFT symbol, the assumed standard is slew rate limited LVTTL with 12 mA drive strength.

The LVTTL OBUFT additionally can support one of two slew rate modes to minimize bus transients. By default, the slew rate for each output buffer is reduced to minimize power bus transients when switching non-critical signals.

LVTTL 3-state output buffers have selectable drive strengths.

The format for LVTTL OBUFT symbol names is as follows.

OBUFT\_<slew\_rate>\_<drive\_strength>

<slew\_rate> can be either F (Fast), or S (Slow) and <drive\_strength> is specified in milliamps (2, 4, 6, 8, 12, 16, or 24).



#### Figure 38: 3-State Output Buffer Symbol (OBUFT

The following list details variations of the OBUFT symbol.

- OBUFT
- OBUFT\_S\_2
- OBUFT\_S\_4
- OBUFT\_S\_6
- OBUFT\_S\_8
- OBUFT\_S\_12
- OBUFT\_S\_16
- OBUFT\_S\_24
- OBUFT\_F\_2
- OBUFT\_F\_4
- OBUFT\_F\_6
- OBUFT\_F\_8
- OBUFT\_F\_12
- OBUFT\_F\_16
- OBUFT\_F\_24
- OBUFT\_LVCMOS2
- OBUFT\_PCI33\_3
- OBUFT\_PCI33\_5
- OBUFT\_PCI66\_3
- OBUFT\_GTL
- OBUFT\_GTLP
- OBUFT\_HSTL\_I
- OBUFT\_HSTL\_III
- OBUFT\_HSTL\_IV
- OBUFT\_SSTL3\_I
- OBUFT\_SSTL3\_II
- OBUFT\_SSTL2\_I
- OBUFT\_SSTL2\_II
- OBUFT\_CTT
- OBUFT\_AGP

The Versatile I/O OBUFT placement restrictions require that within a given V<sub>CCO</sub> bank each OBUFT share the same output source drive voltage. Input buffers of any type and output buffers that do not require V<sub>CCO</sub> can be placed within the same V<sub>CCO</sub> bank.

The LOC property can specify a location for the OBUFT.

3-state output buffers and bidirectional buffers can have either a weak pull-up resistor, a weak pull-down resistor, or a weak "keeper" circuit. Control this feature by adding the appropriate symbol to the output net of the OBUFT (PULLUP, PULLDOWN, or KEEPER).

The weak "keeper" circuit requires the input buffer within the IOB to sample the I/O signal. So, OBUFTs programmed for an I/O standard that requires a  $V_{REF}$  have automatic placement of a  $V_{REF}$  in the bank with an OBUFT configured with a weak "keeper" circuit. This restriction does not affect most circuit design as applications using an OBUFT configured with a weak "keeper" typically implement a bidirectional I/O. In this case the IBUF (and the corresponding  $V_{REF}$ ) are explicitly placed.

The LOC property can specify a location for the OBUFT.

#### IOBUF

Use the IOBUF symbol for bidirectional signals that require both an input buffer and a 3-state output buffer with an active high 3-state pin. The generic input/output buffer IOBUF appears in Figure 39.

The extension to the base name defines which I/O standard the IOBUF uses. With no extension specified for the generic IOBUF symbol, the assumed standard is LVTTL input buffer and slew rate limited LVTTL with 12 mA drive strength for the output buffer.

The LVTTL IOBUF additionally can support one of two slew rate modes to minimize bus transients. By default, the slew rate for each output buffer is reduced to minimize power bus transients when switching non-critical signals.

LVTTL bidirectional buffers have selectable output drive strengths.

The format for LVTTL IOBUF symbol names is as follows:

IOBUF\_<slew\_rate>\_<drive\_strength>

<slew\_rate> can be either F (Fast), or S (Slow) and <drive\_strength> is specified in milliamps (2, 4, 6, 8, 12, 16, or 24).



DS001\_40\_061200

Figure 39: Input/Output Buffer Symbol (IOBUF)

The following list details variations of the IOBUF symbol:

- IOBUF
- IOBUF\_S\_2
- IOBUF\_S\_4
- IOBUF\_S\_6
- IOBUF\_S\_8
- IOBUF\_S\_12
- IOBUF\_S\_16
- IOBUF\_S\_24
- IOBUF\_F\_2
- IOBUF\_F\_4
- IOBUF\_F\_6
- IOBUF\_F\_8
- IOBUF\_F\_12
- IOBUF\_F\_16
- IOBUF\_F\_24
- IOBUF\_LVCMOS2
- IOBUF\_PCI33\_3
- IOBUF\_PCI33\_5
- IOBUF\_PCI66\_3
- IOBUF\_GTL
- IOBUF\_GTLP
- IOBUF\_HSTL\_I
- IOBUF\_HSTL\_III
- IOBUF\_HSTL\_IV
- IOBUF\_SSTL3\_I
- IOBUF\_SSTL3\_II
- IOBUF\_SSTL2\_I
- IOBUF\_SSTL2\_II
- IOBUF\_CTT
- IOBUF\_AGP

When the IOBUF symbol supports an I/O standard such as LVTTL, LVCMOS, or PCI33\_5, the IBUF automatically configures as a 5V tolerant input buffer unless the V<sub>CCO</sub> for the bank is less than 2V. If the single-ended IBUF is placed in a bank with an HSTL standard (V<sub>CCO</sub> < 2V), the input buffer is not 5V tolerant.

The voltage reference signal is "banked" within the Spartan-II device on a half-edge basis such that for all packages there are eight independent  $V_{REF}$  banks internally. See Figure 35, page 32 for a representation of the Spartan-II I/O banks. Within each bank approximately one of every six I/O pins is automatically configured as a  $V_{REF}$  input.

Additional restrictions on the Versatile I/O IOBUF placement require that within a given V<sub>CCO</sub> bank each IOBUF must share the same output source drive voltage. Input buffers of any type and output buffers that do not require V<sub>CCO</sub> can be placed within the same V<sub>CCO</sub> bank. The LOC property can specify a location for the IOBUF.

An optional delay element is associated with the input path in each IOBUF. When the IOBUF drives an input flip-flop within the IOB, the delay element activates by default to ensure a zero hold-time requirement. Override this default with the NODELAY=TRUE property.

In the case when the IOBUF does not drive an input flip-flop within the IOB, the delay element de-activates by default to provide higher performance. To delay the input signal, activate the delay element with the DELAY=TRUE property.

3-state output buffers and bidirectional buffers can have either a weak pull-up resistor, a weak pull-down resistor, or a weak "keeper" circuit. Control this feature by adding the appropriate symbol to the output net of the IOBUF (PULLUP, PULLDOWN, or KEEPER).

## **Versatile I/O Properties**

Access to some of the Versatile I/O features (for example, location constraints, input delay, output drive strength, and slew rate) is available through properties associated with these features.

#### Input Delay Properties

An optional delay element is associated with each IBUF. When the IBUF drives a flip-flop within the IOB, the delay element activates by default to ensure a zero hold-time requirement. Use the NODELAY=TRUE property to override this default.

In the case when the IBUF does not drive a flip-flop within the IOB, the delay element by default de-activates to provide higher performance. To delay the input signal, activate the delay element with the DELAY=TRUE property.

## IOB Flip-Flop/Latch Property

The I/O Block (IOB) includes an optional register on the input path, an optional register on the output path, and an optional register on the 3-state control pin. The design implementation software automatically takes advantage of these registers when the following option for the Map program is specified:

#### map -pr b <filename>

Alternatively, the IOB = TRUE property can be placed on a register to force the mapper to place the register in an IOB.

#### **Location Constraints**

Specify the location of each Versatile I/O symbol with the location constraint LOC attached to the Versatile I/O symbol. The external port identifier indicates the value of the location constrain. The format of the port identifier depends on the package chosen for the specific design.

The LOC properties use the following form:

LOC=A42 LOC=P37

#### **Output Slew Rate Property**

As mentioned above, a variety of symbol names provide the option of choosing the desired slew rate for the output buffers. In the case of the LVTTL output buffers (OBUF, OBUFT, and IOBUF), slew rate control can be alternatively programed with the SLEW= property. By default, the slew rate for each output buffer is reduced to minimize power bus transients when switching non-critical signals. The SLEW= property has one of the two following values.

SLEW=SLOW

SLEW=FAST

#### **Output Drive Strength Property**

The desired output drive strength can be additionally specified by choosing the appropriate library symbol. The Xilinx library also provides an alternative method for specifying this feature. For the LVTTL output buffers (OBUF, OBUFT, and IOBUF, the desired drive strength can be specified with the DRIVE= property. This property could have one of the following seven values.

DRIVE=2 DRIVE=4 DRIVE=6 DRIVE=8 DRIVE=12 (Default) DRIVE=16 DRIVE=24

## **Design Considerations**

#### Reference Voltage (V<sub>REF</sub>) Pins

Low-voltage I/O standards with a differential amplifier input buffer require an input reference voltage ( $V_{REF}$ ). Provide the  $V_{RFF}$  as an external signal to the device.

The voltage reference signal is "banked" within the device on a half-edge basis such that for all packages there are eight independent  $V_{REF}$  banks internally. See Figure 35, page 32 for a representation of the I/O banks. Within each bank approximately one of every six I/O pins is automatically configured as a  $V_{REF}$  input.

Within each  $V_{REF}$  bank, any input buffers that require a  $V_{REF}$  signal must be of the same type. Output buffers of any

type and input buffers can be placed without requiring a reference voltage within the same  $V_{\mbox{\scriptsize REF}}$  bank.

#### Output Drive Source Voltage (V<sub>CCO</sub>) Pins

Many of the low voltage I/O standards supported by Versatile I/Os require a different output drive source voltage ( $V_{CCO}$ ). As a result each device can often have to support multiple output drive source voltages.

The V<sub>CCO</sub> supplies are internally tied together for some packages. The VQ100 and the PQ208 provide one combined V<sub>CCO</sub> supply. The TQ144 and the CS144 packages provide four independent V<sub>CCO</sub> supplies. The FG256 and the FG456 provide eight independent V<sub>CCO</sub> supplies.

Output buffers within a given V<sub>CCO</sub> bank must share the same output drive source voltage. Input buffers for LVTTL, LVCMOS2, PCI33\_3, and PCI 66\_3 use the V<sub>CCO</sub> voltage for Input V<sub>CCO</sub> voltage.

#### Transmission Line Effects

The delay of an electrical signal along a wire is dominated by the rise and fall times when the signal travels a short distance. Transmission line delays vary with inductance and capacitance, but a well-designed board can experience delays of approximately 180 ps per inch.

Transmission line effects, or reflections, typically start at 1.5" for fast (1.5 ns) rise and fall times. Poor (or non-existent) termination or changes in the transmission line impedance cause these reflections and can cause additional delay in longer traces. As system speeds continue to increase, the effect of I/O delays can become a limiting factor and therefore transmission line termination becomes increasingly more important.

#### **Termination Techniques**

A variety of termination techniques reduce the impact of transmission line effects.

The following lists output termination techniques:

None Series Parallel (Shunt) Series and Parallel (Series-Shunt)

Input termination techniques include the following:

None Parallel (Shunt) These termination techniques can be applied in any combination. A generic example of each combination of termination methods appears in Figure 40.





Unterminated Output Driving a Parallel Terminated Input



a Parallel Terminated Input

Series Terminated Output Driving



Series-Parallel Terminated Output Driving a Parallel Terminated Input

Series Terminated Output



DS001\_41\_032300

Figure 40: Overview of Standard Input and Output Termination Methods

#### Simultaneous Switching Guidelines

Ground bounce can occur with high-speed digital ICs when multiple outputs change states simultaneously, causing undesired transient behavior on an output, or in the internal logic. This problem is also referred to as the Simultaneous Switching Output (SSO) problem.

Ground bounce is primarily due to current changes in the combined inductance of ground pins, bond wires, and ground metallization. The IC internal ground level deviates from the external system ground level for a short duration (a few nanoseconds) after multiple outputs change state simultaneously.

Ground bounce affects stable Low outputs and all inputs because they interpret the incoming signal by comparing it to the internal ground. If the ground bounce amplitude exceeds the actual instantaneous noise margin, then a non-changing input can be interpreted as a short pulse with a polarity opposite to the ground bounce.

Table 17 provides the guidelines for the maximum numberof simultaneously switching outputs allowed per outputpower/ground pair to avoid the effects of ground bounce.Refer to Table 18 for the number of effective output

power/ground pairs for each Spartan-II device and package combination.

# Table 17: Maximum Number of SimultaneouslySwitching Outputs per Power/Ground Pair

	Pacl	kage
Standard	CS, FG	PQ, TQ, VQ
LVTTL Slow Slew Rate, 2 mA drive	68	36
LVTTL Slow Slew Rate, 4 mA drive	41	20
LVTTL Slow Slew Rate, 6 mA drive	29	15
LVTTL Slow Slew Rate, 8 mA drive	22	12
LVTTL Slow Slew Rate, 12 mA drive	17	9
LVTTL Slow Slew Rate, 16 mA drive	14	7
LVTTL Slow Slew Rate, 24 mA drive	9	5
LVTTL Fast Slew Rate, 2 mA drive	40	21
LVTTL Fast Slew Rate, 4 mA drive	24	12
LVTTL Fast Slew Rate, 6 mA drive	17	9
LVTTL Fast Slew Rate, 8 mA drive	13	7
LVTTL Fast Slew Rate, 12 mA drive	10	5
LVTTL Fast Slew Rate, 16 mA drive	8	4
LVTTL Fast Slew Rate, 24 mA drive	5	3
LVCMOS2	10	5
PCI	8	4
GTL	4	4
GTL+	4	4
HSTL Class I	18	9
HSTL Class III	9	5
HSTL Class IV	5	3
SSTL2 Class I	15	8
SSTL2 Class II	10	5
SSTL3 Class I	11	6
SSTL3 Class II	7	4
СТТ	14	7
AGP	9	5

Notes:

1. This analysis assumes a 35 pF load for each output.

	Spartan-II Devices											
Pkg.	XC2S 15											
VQ100	8	8	-	-	-	-						
CS144	12	12	-	-	-	-						
TQ144	12	12	12	12	-	-						
PQ208	-	16	16	16	16	16						
FG256	-	-	16	16	16	16						
FG456	-	-	-	48	48	48						

# Table 18: Effective Output Power/Ground Pairs for Spartan-II Devices

## **Termination Examples**

Creating a design with the Versatile I/O features requires the instantiation of the desired library symbol within the design code. At the board level, designers need to know the termination techniques required for each I/O standard.

This section describes some common application examples illustrating the termination techniques recommended by each of the standards supported by the Versatile I/O features. For a full range of accepted values for the DC voltage specifications for each standard, refer to the table associated with each figure.

The resistors used in each termination technique example and the transmission lines depicted represent board level components and are not meant to represent components on the device.

#### GTL

A sample circuit illustrating a valid termination technique for GTL is shown in Figure 41. Table 19 lists DC voltage specifications.

GTL



Figure 41: Terminated GTL

#### Table 19: GTL Voltage Specifications

Parameter	Min	Тур	Max
V <sub>CCO</sub>	-	N/A	-
$V_{REF} = N \times V_{TT}^{(1)}$	0.74	0.8	0.86
V <sub>TT</sub>	1.14	1.2	1.26
$V_{IH} \ge V_{REF} + 0.05$	0.79	0.85	-
$V_{IL} \le V_{REF} - 0.05$	-	0.75	0.81
V <sub>OH</sub>	-	-	-
V <sub>OL</sub>	-	0.2	0.4
I <sub>OH</sub> at V <sub>OH</sub> (mA)	-	-	-
I <sub>OL</sub> at V <sub>OL</sub> (mA) at 0.4V	32	-	-
$I_{OL}$ at $V_{OL}$ (mA) at 0.2V	-	-	40

Notes:

1. N must be greater than or equal to 0.653 and less than or equal to 0.68.

#### GTL+

A sample circuit illustrating a valid termination technique for GTL+ appears in Figure 42. DC voltage specifications appear in Table 20 .



Figure 42: Terminated GTL+

#### Table 20: GTL+ Voltage Specifications

Parameter	Min	Тур	Мах
V <sub>CCO</sub>	-	-	-
$V_{\text{REF}} = N \times V_{\text{TT}}^{(1)}$	0.88	1.0	1.12
V <sub>TT</sub>	1.35	1.5	1.65
$V_{IH} \ge V_{REF} + 0.1$	0.98	1.1	-
$V_{IL} \le V_{REF} - 0.1$	-	0.9	1.02
V <sub>OH</sub>	-	-	-
V <sub>OL</sub>	0.3	0.45	0.6
I <sub>OH</sub> at V <sub>OH</sub> (mA)	-	-	-
I <sub>OL</sub> at V <sub>OL</sub> (mA) at 0.6V	36	-	-
$I_{OL}$ at $V_{OL}$ (mA) at 0.3V	-	-	48

#### Notes:

#### HSTL Class I

A sample circuit illustrating a valid termination technique for HSTL\_I appears in Figure 43. DC voltage specifications appear in Table 21.





Figure 43: Terminated HSTL Class I

#### Table 21: HSTL Class I Voltage Specification

Parameter	Min	Тур	Max
V <sub>CCO</sub>	1.40	1.50	1.60
V <sub>REF</sub>	0.68	0.75	0.90
V <sub>TT</sub>	-	$V_{CCO}  imes 0.5$	-
V <sub>IH</sub>	V <sub>REF</sub> + 0.1	-	-
V <sub>IL</sub>	-	-	V <sub>REF</sub> – 0.1
V <sub>OH</sub>	V <sub>CCO</sub> – 0.4	-	-
V <sub>OL</sub>			0.4
I <sub>OH</sub> at V <sub>OH</sub> (mA)	-8	-	-
I <sub>OL</sub> at V <sub>OL</sub> (mA)	8	-	-

<sup>1.</sup> N must be greater than or equal to 0.653 and less than or equal to 0.68.

#### **HTSL Class III**

A sample circuit illustrating a valid termination technique for HSTL\_III appears in Figure 44. DC voltage specifications appear in Table 22.

#### HSTL Class III



Figure 44: Terminated HSTL Class III

#### Table 22: HSTL Class III Voltage Specification

Parameter	Min	Тур	Мах
V <sub>CCO</sub>	1.40	1.50	1.60
V <sub>REF</sub> <sup>(1)</sup>	-	0.90	-
V <sub>TT</sub>	-	V <sub>CCO</sub>	-
V <sub>IH</sub>	V <sub>REF</sub> + 0.1	-	-
V <sub>IL</sub>	-	-	$V_{REF} - 0.1$
V <sub>OH</sub>	V <sub>CCO</sub> – 0.4	-	-
V <sub>OL</sub>	-	-	0.4
I <sub>OH</sub> at V <sub>OH</sub> (mA)	-8	-	-
I <sub>OL</sub> at V <sub>OL</sub> (mA)	24	-	-

#### Notes:

1. Per EIA/JESD8-6, "The value of V<sub>REF</sub> is to be selected by the user to provide optimum noise margin in the use conditions specified by the user."

#### **HTSL Class IV**

A sample circuit illustrating a valid termination technique for HSTL\_IV appears in Figure 45.DC voltage specifications appear in Table 22



Figure 45: Terminated HSTL Class IV

#### Table 23: HSTL Class IV Voltage Specification

Parameter	Min	Тур	Max
V <sub>CCO</sub>	1.40	1.50	1.60
V <sub>REF</sub>	-	0.90	-
V <sub>TT</sub>	-	V <sub>CCO</sub>	-
V <sub>IH</sub>	V <sub>REF</sub> + 0.1	-	-
V <sub>IL</sub>	-	-	V <sub>REF</sub> – 0.1
V <sub>OH</sub>	V <sub>CCO</sub> – 0.4	-	-
V <sub>OL</sub>	-	-	0.4
I <sub>OH</sub> at V <sub>OH</sub> (mA)	-8	-	-
I <sub>OL</sub> at V <sub>OL</sub> (mA)	48	-	-

#### Notes:

 Per EIA/JESD8-6, "The value of V<sub>REF</sub> is to be selected by the user to provide optimum noise margin in the use conditions specified by the user."

## SSTL3 Class I

A sample circuit illustrating a valid termination technique for SSTL3\_I appears in Figure 46. DC voltage specifications appear in Table 24.

#### SSTL3 Class I



Figure 46: Terminated SSTL3 Class I

#### Table 24: SSTL3\_I Voltage Specifications

Parameter	Min	Тур	Max
V <sub>CCO</sub>	3.0	3.3	3.6
$V_{REF} = 0.45 \times V_{CCO}$	1.3	1.5	1.7
V <sub>TT</sub> = V <sub>REF</sub>	1.3	1.5	1.7
$V_{IH} \ge V_{REF} + 0.2$	1.5	1.7	3.9 <sup>(1)</sup>
$V_{IL} \le V_{REF} - 0.2$	-0.3 <sup>(2)</sup>	1.3	1.5
$V_{OH} \ge V_{REF} + 0.6$	1.9	-	-
$V_{OL} \le V_{REF} - 0.6$	-	-	1.1
I <sub>OH</sub> at V <sub>OH</sub> (mA)	-8	-	-
I <sub>OL</sub> at V <sub>OL</sub> (mA)	8	-	-

#### Notes:

1.  $V_{IH}$  maximum is  $V_{CCO}$  + 0.3.

2. V<sub>IL</sub> minimum does not conform to the formula.

#### SSTL3 Class II

A sample circuit illustrating a valid termination technique for SSTL3\_II appears in Figure 47. DC voltage specifications appear in Table 25.



Figure 47: Terminated SSTL3 Class II

#### Table 25: SSTL3\_II Voltage Specifications

Min	Тур	Мах
3.0	3.3	3.6
1.3	1.5	1.7
1.3	1.5	1.7
1.5	1.7	3.9 <sup>(1)</sup>
-0.3 <sup>(2)</sup>	1.3	1.5
2.1	-	-
-	-	0.9
-16	-	-
16	-	-
	$3.0$ $1.3$ $1.3$ $1.5$ $-0.3^{(2)}$ $2.1$ $-$ $-16$	$\begin{array}{c cccc} 3.0 & 3.3 \\ \hline 3.0 & 3.3 \\ \hline 1.3 & 1.5 \\ \hline 1.3 & 1.5 \\ \hline 1.5 & 1.7 \\ \hline -0.3^{(2)} & 1.3 \\ \hline 2.1 & - \\ \hline - & - \\ \hline -16 & - \end{array}$

#### Notes:

1.  $V_{IH}$  maximum is  $V_{CCO}$  + 0.3

2.  $V_{IL}$  minimum does not conform to the formula

#### SSTL2\_I

A sample circuit illustrating a valid termination technique for SSTL2\_I appears in Figure 48. DC voltage specifications appear in Table 26

#### SSTL2 Class I



Figure 48: Terminated SSTL2 Class I

#### Table 26: SSTL2\_I Voltage Specifications

Parameter	Min	Тур	Max
V <sub>CCO</sub>	2.3	2.5	2.7
$V_{REF} = 0.5 \times V_{CCO}$	1.15	1.25	1.35
$V_{TT} = V_{REF} + N^{(1)}$	1.11	1.25	1.39
$V_{IH} \ge V_{REF} + 0.18$	1.33	1.43	3.0 <sup>(2)</sup>
$V_{IL} \le V_{REF} - 0.18$	-0.3 <sup>(3)</sup>	1.07	1.17
$V_{OH} \ge V_{REF} + 0.61$	1.76	-	-
$V_{OL} \le V_{REF} - 0.61$	-	-	0.74
I <sub>OH</sub> at V <sub>OH</sub> (mA)	-7.6	-	-
I <sub>OL</sub> at V <sub>OL</sub> (mA)	7.6	-	-

#### Notes:

- 1. N must be greater than or equal to -0.04 and less than or equal to 0.04.
- 2.  $V_{IH}$  maximum is  $V_{CCO}$  + 0.3.
- 3.  $V_{IL}$  minimum does not conform to the formula.

## SSTL2 Class II

A sample circuit illustrating a valid termination technique for SSTL2\_II appears in Figure 49. DC voltage specifications appear in Table 27.



Figure 49: Terminated SSTL2 Class II

#### Table 27: SSTL2\_II Voltage Specifications

Parameter	Min	Тур	Max
V <sub>CCO</sub>	2.3	2.5	2.7
$V_{REF} = 0.5 \times V_{CCO}$	1.15	1.25	1.35
$V_{TT} = V_{REF} + N^{(1)}$	1.11	1.25	1.39
$V_{IH} \ge V_{REF} + 0.18$	1.33	1.43	3.0 <sup>(2)</sup>
$V_{IL} \leq V_{REF} - 0.18$	-0.3 <sup>(3)</sup>	1.07	1.17
$V_{OH} \ge V_{REF} + 0.8$	1.95	-	-
$V_{OL} \le V_{REF} - 0.8$	-	-	0.55
I <sub>OH</sub> at V <sub>OH</sub> (mA)	-15.2	_	-
I <sub>OL</sub> at V <sub>OL</sub> (mA)	15.2	_	_

#### Notes:

1. N must be greater than or equal to -0.04 and less than or equal to 0.04.

- 2.  $V_{IH}$  maximum is  $V_{CCO}$  + 0.3.
- 3. V<sub>IL</sub> minimum does not conform to the formula.

#### СТТ

A sample circuit illustrating a valid termination technique for CTT appear in Figure 50. DC voltage specifications appear in Table 28 .

#### стт



Figure 50: Terminated CTT

#### Table 28: CTT Voltage Specifications

Parameter	Min	Тур	Max
V <sub>CCO</sub>	2.05 <sup>(1)</sup>	3.3	3.6
V <sub>REF</sub>	1.35	1.5	1.65
V <sub>TT</sub>	1.35	1.5	1.65
$V_{IH} \ge V_{REF} + 0.2$	1.55	1.7	-
$V_{IL} \le V_{REF} - 0.2$	-	1.3	1.45
$V_{OH} \ge V_{REF} + 0.4$	1.75	1.9	-
$V_{OL} \le V_{REF} - 0.4$	-	1.1	1.25
I <sub>OH</sub> at V <sub>OH</sub> (mA)	-8	-	-
I <sub>OL</sub> at V <sub>OL</sub> (mA)	8	-	-

#### Notes:

1. Timing delays are calculated based on  $V_{CCO}$  min of 3.0V.

#### PCI33\_3 and PCI66\_3

PCI33\_3 or PCI66\_3 require no termination. DC voltage specifications appear in Table 29.

#### Table 29: PCI33\_3 and PCI66\_3 Voltage Specifications

Parameter	Min	Тур	Max
V <sub>CCO</sub>	3.0	3.3	3.6
V <sub>REF</sub>	-	-	-
V <sub>TT</sub>	-	-	-
$V_{IH} = 0.5 \times V_{CCO}$	1.5	1.65	V <sub>CCO</sub> + 0.5
$V_{IL} = 0.3 \times V_{CCO}$	-0.5	0.99	1.08
$V_{OH} = 0.9 \times V_{CCO}$	2.7	-	-
$V_{OL} = 0.1 \times V_{CCO}$	-	-	0.36
I <sub>OH</sub> at V <sub>OH</sub> (mA)	Note 1	-	-
I <sub>OL</sub> at V <sub>OL</sub> (mA)	Note 1	-	-

#### Notes:

1. Tested according to the relevant specification.

#### PCI33\_5

PCI33\_5 requires no termination. DC voltage specifications appear in Table 30.

#### Table 30: PCI33\_5 Voltage Specifications

Parameter	Min	Тур	Max
V <sub>CCO</sub>	3.0	3.3	3.6
V <sub>REF</sub>	-	-	-
V <sub>TT</sub>	-	-	-
V <sub>IH</sub>	1.425	1.5	5.5
V <sub>IL</sub>	-0.5	1.0	1.05
V <sub>OH</sub>	2.4	-	-
V <sub>OL</sub>	-	-	0.55
I <sub>OH</sub> at V <sub>OH</sub> (mA)	Note 1	-	-
I <sub>OL</sub> at V <sub>OL</sub> (mA)	Note 1	-	-

#### Notes:

1. Tested according to the relevant specification.

#### LVTTL

LVTTL requires no termination. DC voltage specifications appears in Table 31.

#### Table 31: LVTTL Voltage Specifications

Parameter	Min	Тур	Max
V <sub>CCO</sub>	3.0	3.3	3.6
V <sub>REF</sub>	-	-	-
V <sub>TT</sub>	-	-	-
V <sub>IH</sub>	2.0	-	3.6
V <sub>IL</sub>	-0.5	-	0.8
V <sub>OH</sub>	2.4	-	-
V <sub>OL</sub>	-	-	0.4
I <sub>OH</sub> at V <sub>OH</sub> (mA)	-24	-	-
I <sub>OL</sub> at V <sub>OL</sub> (mA)	24	-	-

#### Notes:

1.  $V_{OL}$  and  $V_{OH}$  for lower drive currents sample tested.

#### LVCMOS2

LVCMOS2 requires no termination. DC voltage specifications appear in Table 32.

#### Table 32: LVCMOS2 Voltage Specifications

Parameter	Min	Тур	Max	
V <sub>CCO</sub>	2.3	2.5	2.7	
V <sub>REF</sub>	-	-	-	
V <sub>TT</sub>	-	-	-	
V <sub>IH</sub>	1.7 -0.5	-	3.6 0.7	
V <sub>IL</sub>				
V <sub>OH</sub>	1.9	-	-	
V <sub>OL</sub>	-	-	0.4	
I <sub>OH</sub> at V <sub>OH</sub> (mA)	-12	-	-	
I <sub>OL</sub> at V <sub>OL</sub> (mA)	12	-	-	

#### AGP-2X

The specification for the AGP-2X standard does not document a recommended termination technique. DC voltage specifications appear in Table 33.

#### Table 33: AGP-2X Voltage Specifications

Parameter	Min	Тур	Max
V <sub>CCO</sub>	3.0	3.3	3.6
$V_{REF} = N \times V_{CCO}^{(1)}$	1.17	1.32	1.48
V <sub>TT</sub>	-	-	-
$V_{IH} \ge V_{REF} + 0.2$	1.37	1.52	-
$V_{IL} \le V_{REF} - 0.2$	-	1.12	1.28
$V_{OH} \ge 0.9 \times V_{CCO}$	2.7	3.0	-
$V_{OL} \le 0.1 \times V_{CCO}$	-	0.33	0.36
I <sub>OH</sub> at V <sub>OH</sub> (mA)	Note 2	-	-
I <sub>OL</sub> at V <sub>OL</sub> (mA)	Note 2	-	-

#### Notes:

- 1. N must be greater than or equal to 0.39 and less than or equal to 0.41.
- 2. Tested according to the relevant specification.

# **Revision History**

Version No.	Date	Description	
2.0	09/18/00	Sectioned the Spartan-II Family data sheet into four modules. Corrected banking description.	
2.1	03/05/01	Clarified guidelines for applying power to $V_{\mbox{CCINT}}$ and $V_{\mbox{CCO}}$	

# The Spartan-II Family Data Sheet

DS001-1, Spartan-II 2.5V FPGA Family: Introduction and Ordering Information (Module 1)

DS001-2, Spartan-II 2.5V FPGA Family: Functional Description (Module 2)

DS001-3, Spartan-II 2.5V FPGA Family: DC and Switching Characteristics (Module 3)

DS001-4, Spartan-II 2.5V FPGA Family: Pinout Tables (Module 4)